

Nanofabrication for Patterned Magnetic Media

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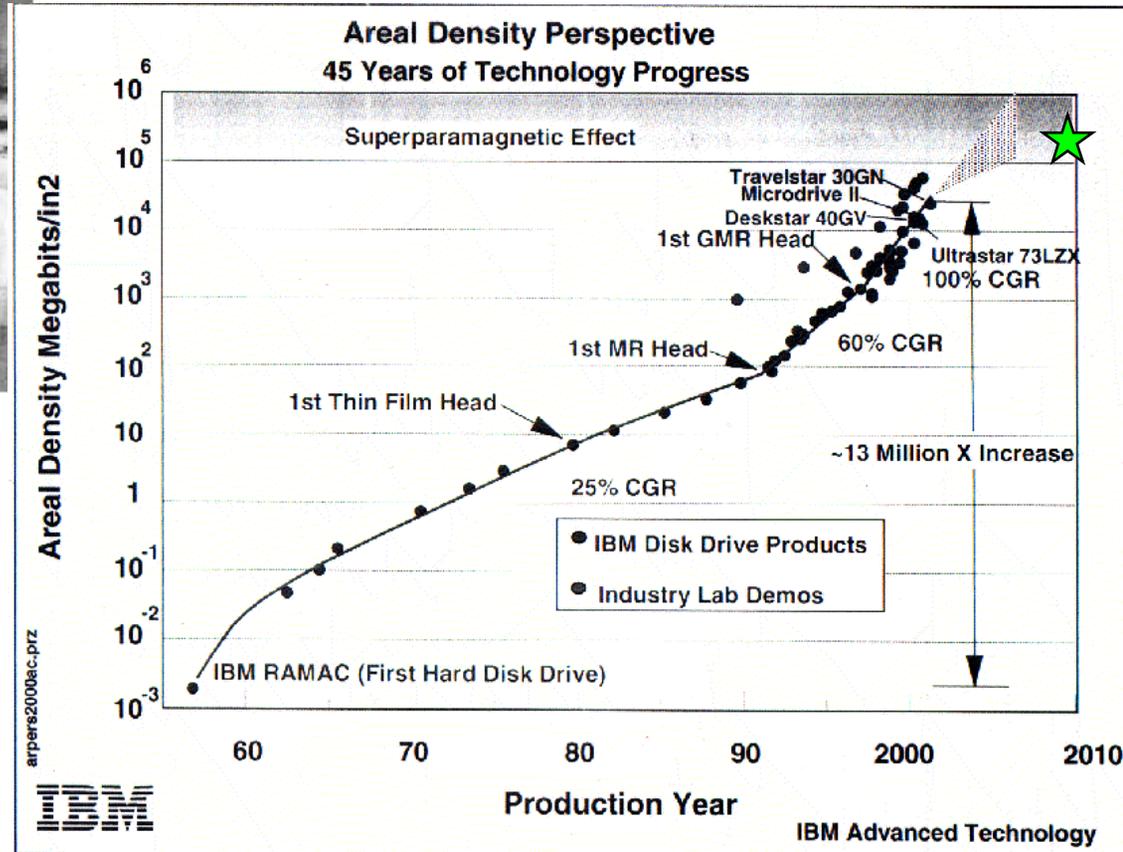
 Hitachi Global Storage Technologies

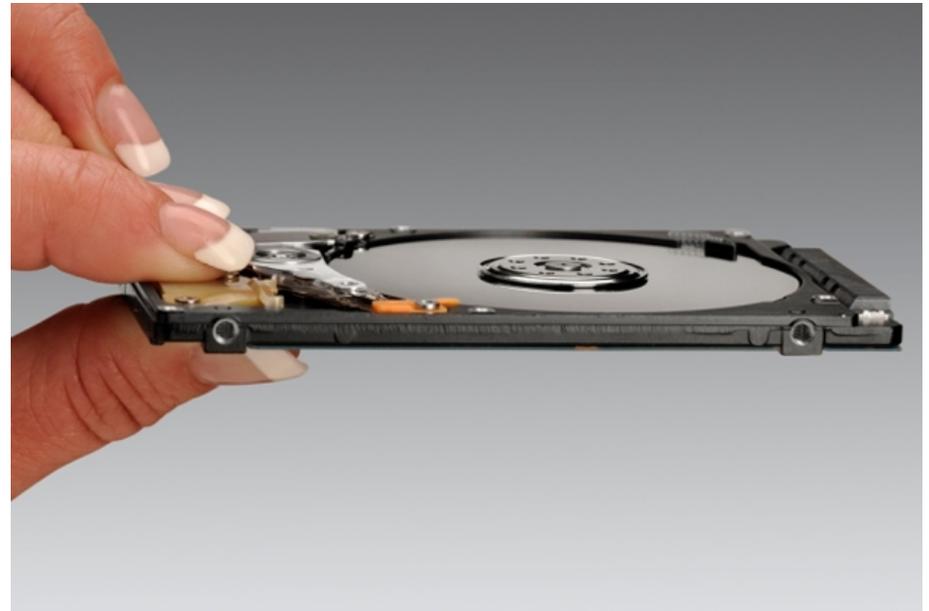


IBM Disk Fabrication 1956



- Areal storage density has been the driving factor for the hard drive industry
- Since 1956 density storage has increased 150 million times
- Hitachi purchased the IBM HDD business in 2003
 - Hitachi Global Storage Technologies





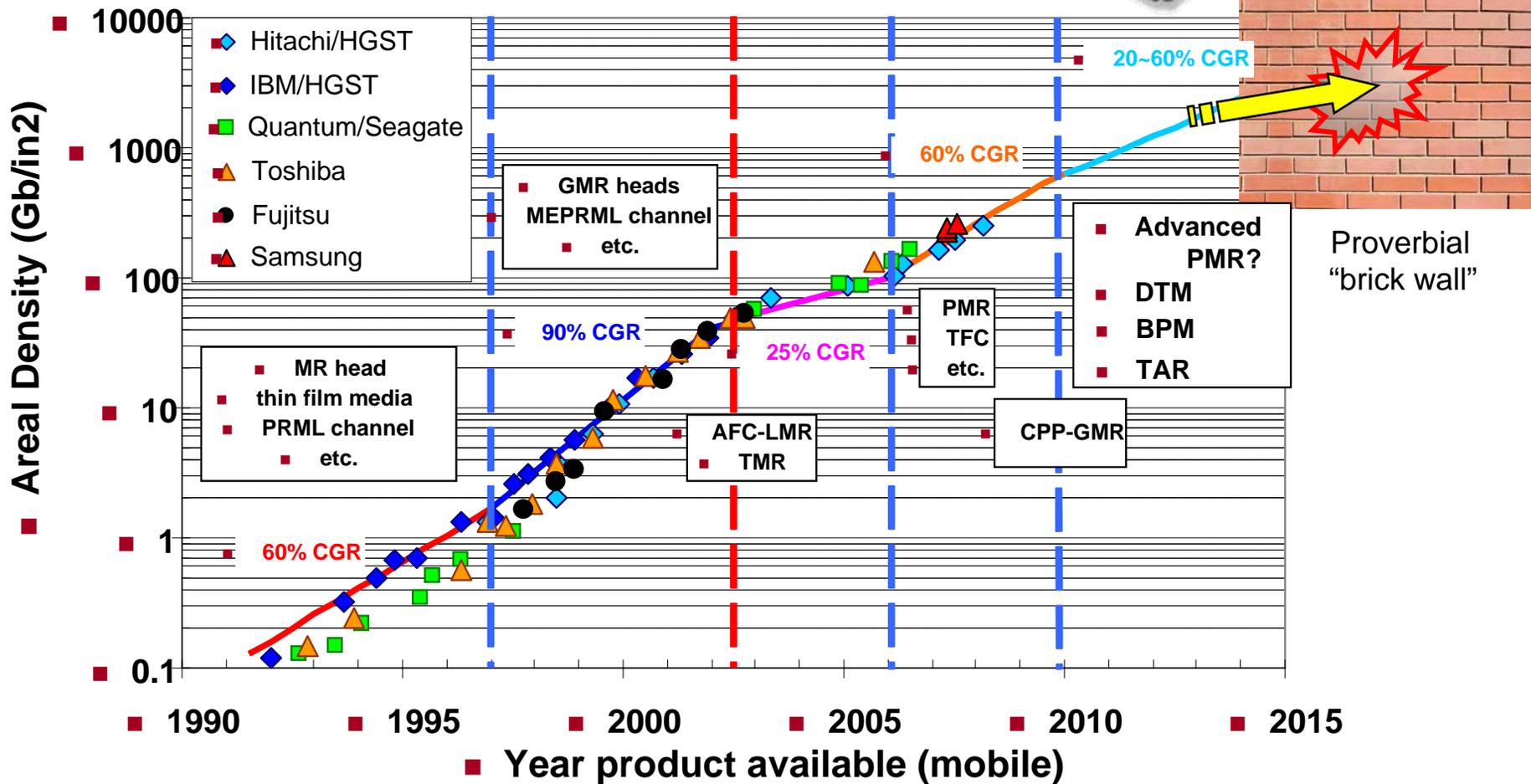
- In 1956, the IBM 350 could store 5MB of data
 - Enough room for about two MP3 files
- HGST's latest 7mm thick Z-series drive holds 320GB

The Areal Density Trend

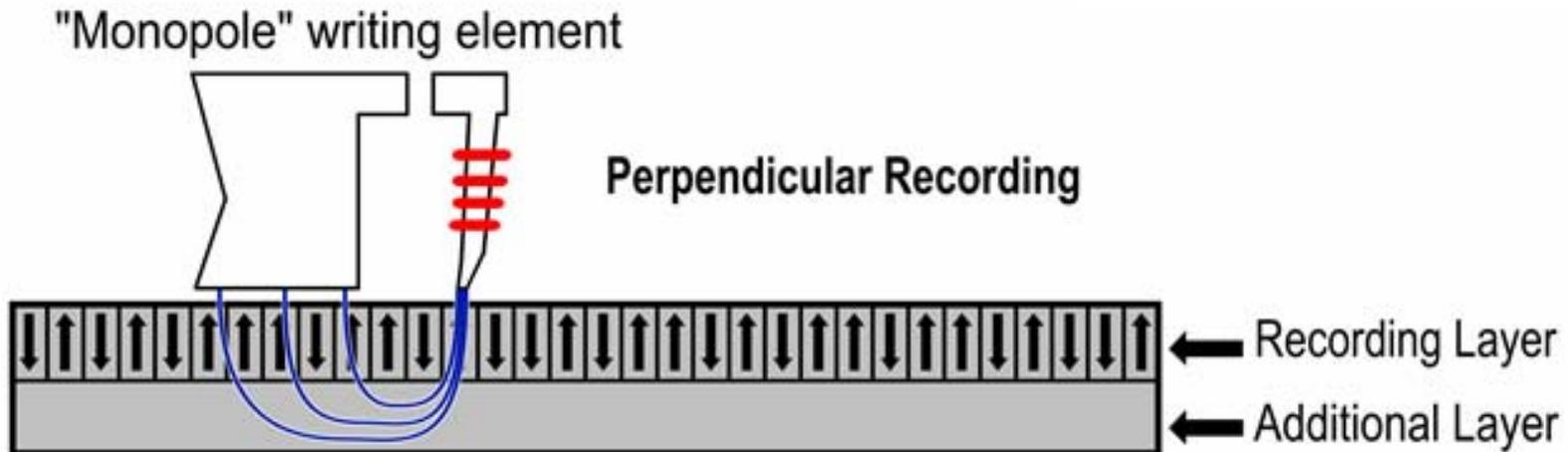
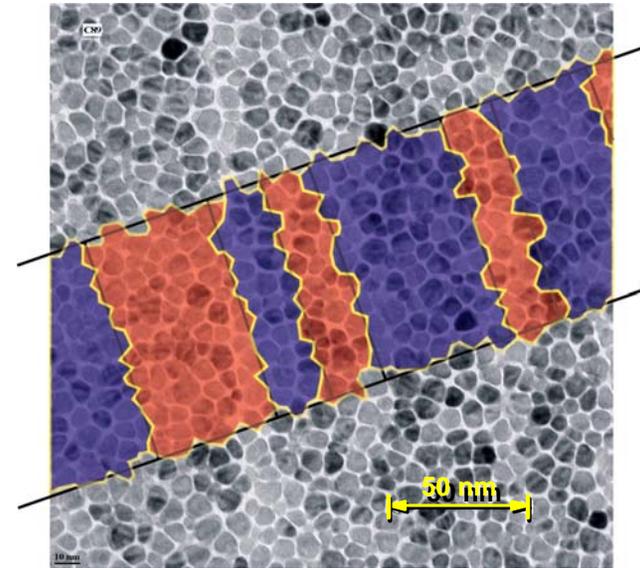


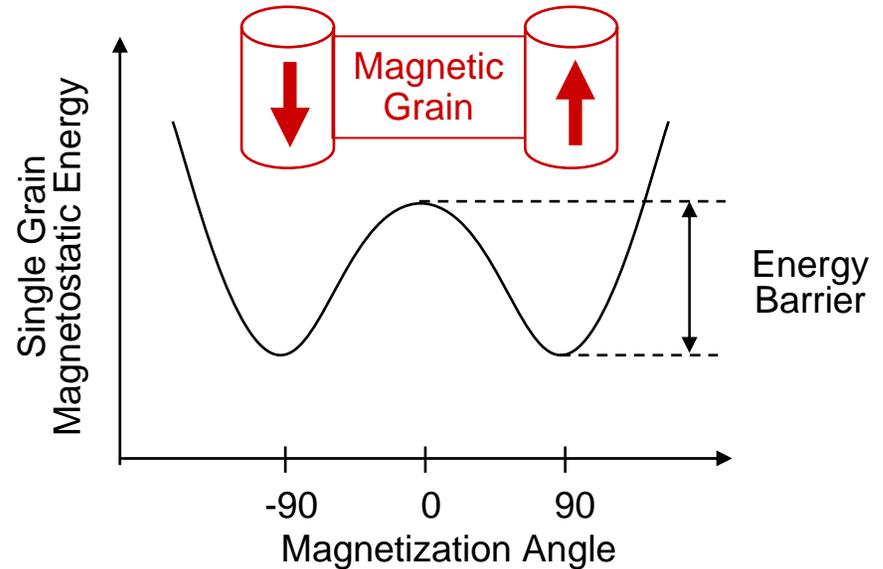
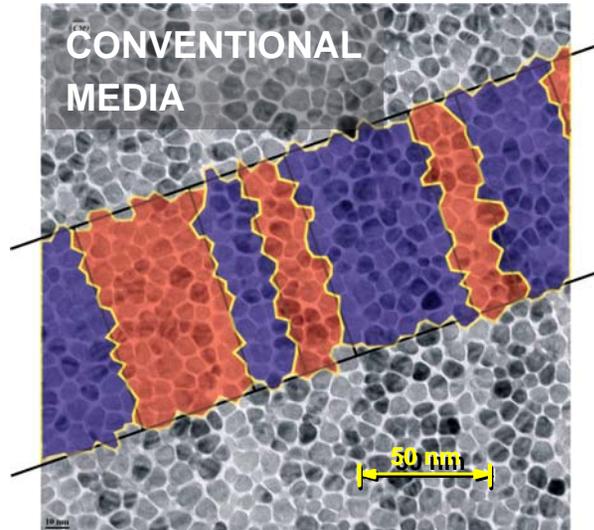
After 50 years of continuous progress...

...will we hit the brick wall?



- Magnetic data storage relies on a thin film of granular magnetic media
- A read/write head flies above the spinning hard disk
- A small coil and pole tip generate a strong field to magnetize the media up or down
- A GMR sensor is used to read back the magnetic signal





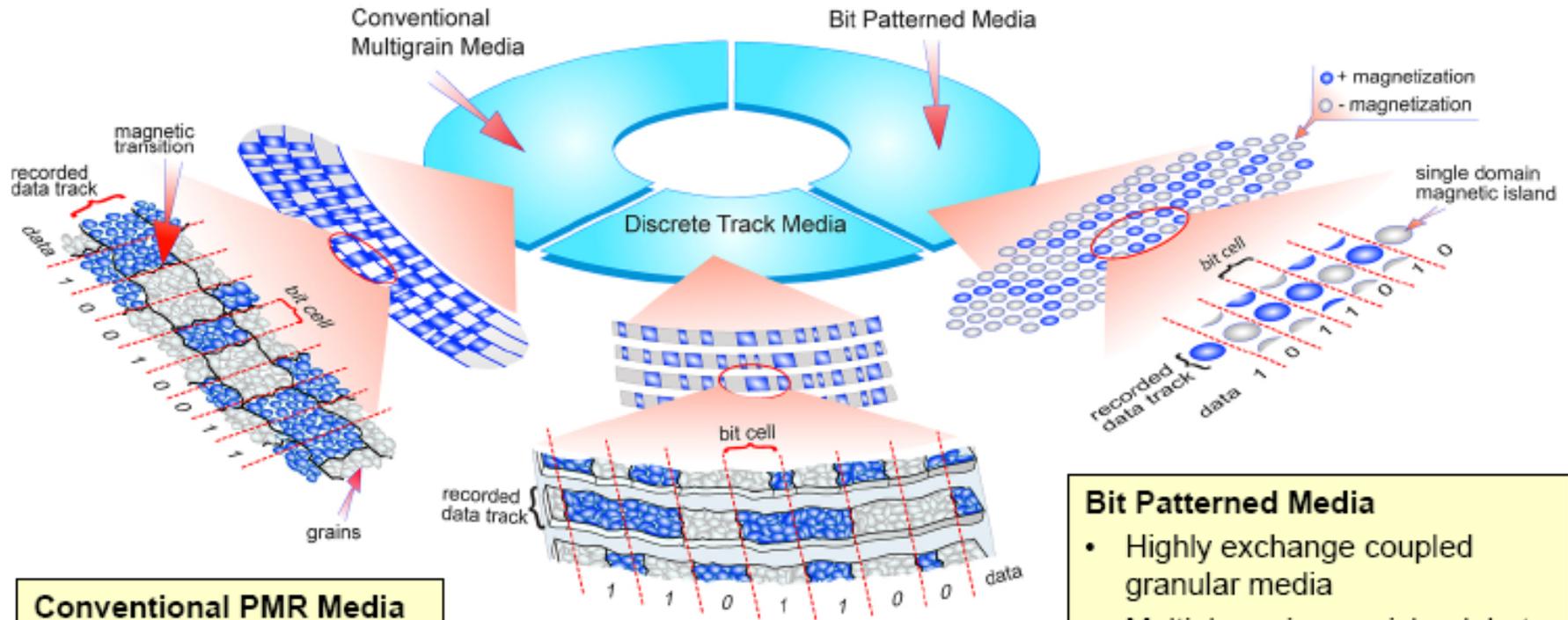
Magnetic Stability: $\frac{\text{energy barrier}}{\text{thermal energy}} \propto \frac{\text{anisotropy} \times \text{volume}}{k_B \times \text{temperature}} = \frac{K_u V}{k_B T} > 70$

GRANULAR MEDIA PROBLEMS:

- To increase density, need smaller grains
- Smaller grains are thermally unstable
- To avoid thermal instability, increase grain anisotropy K_u
- This increases the medium coercivity and makes the medium more difficult to write

SOLUTIONS:

- Work with higher anisotropy:
 - Capped and exchange spring media
 - Thermally assisted recording (TAR)
- **Work with larger 'grains': patterned media**



Conventional PMR Media

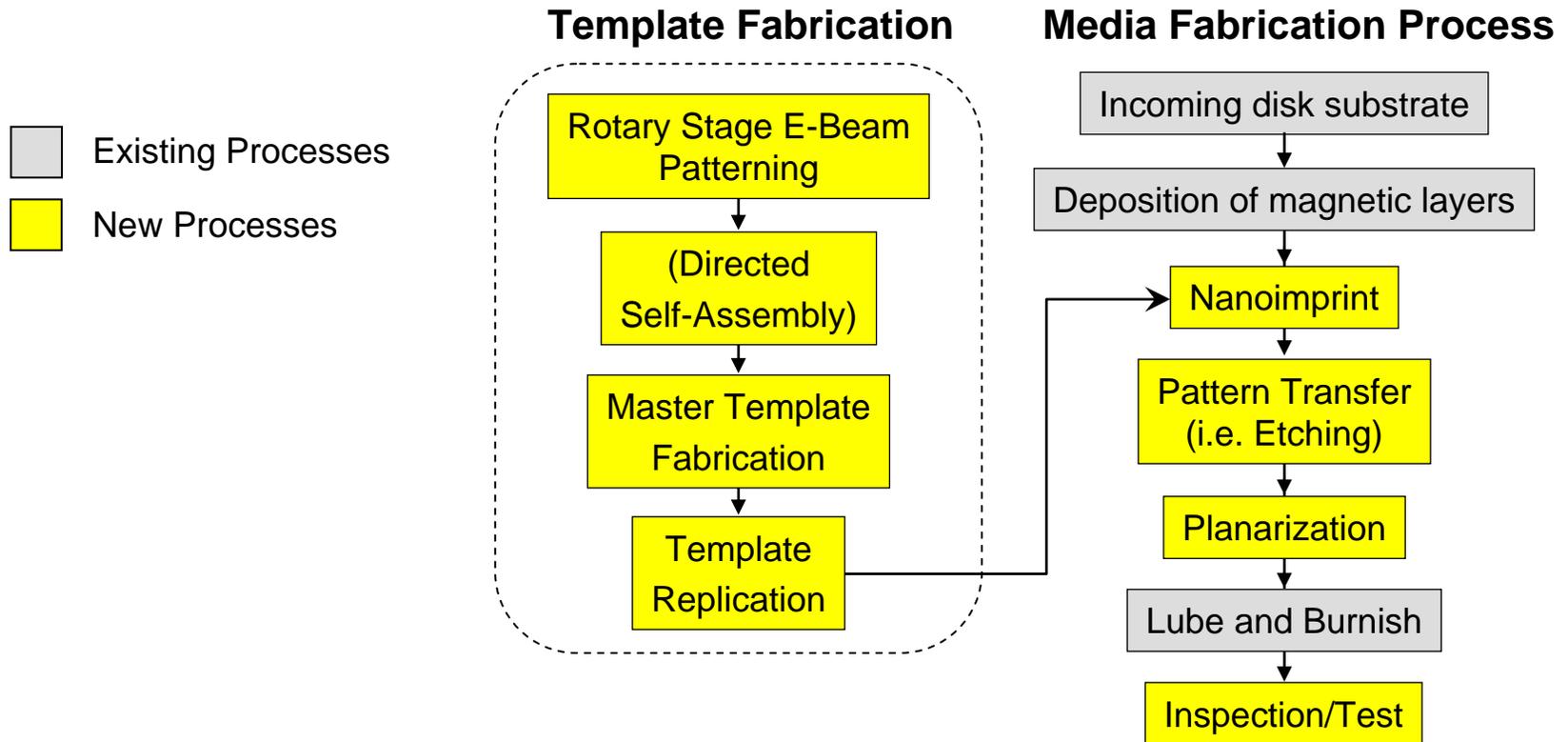
- Continuous granular recording layer
- Multiple grains per bit
- Boundaries between bits determined by grains
- Thermal stability unit is 1 grain (~ 6 nm diam.)

Discrete Track Media

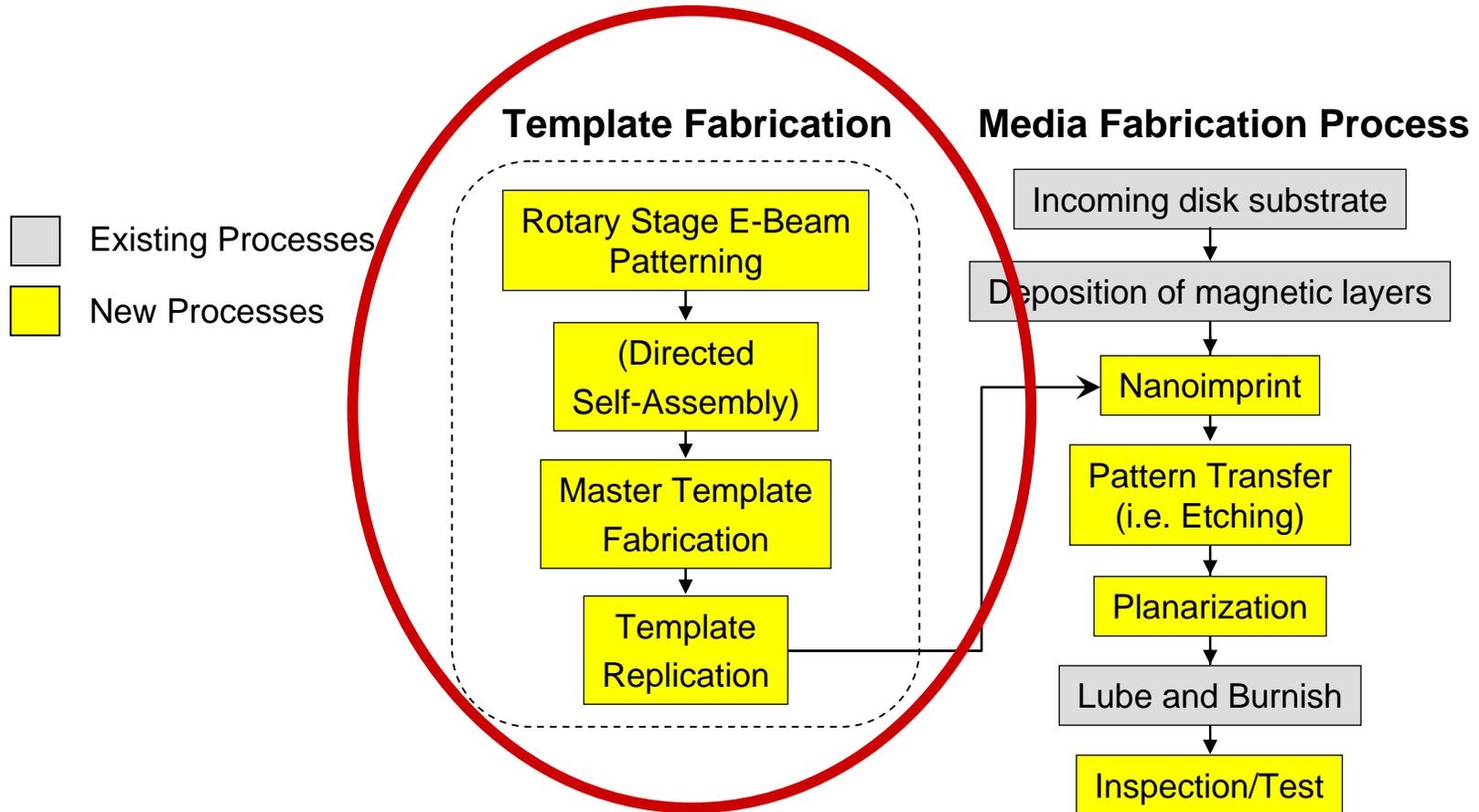
- Conventional PMR media, with patterned tracks
- Multiple grains per bit
- Eliminates track edge noise and reduces adjacent track interference
- Thermal stability unit is still 1 grain (~ 6 nm diam.)

Bit Patterned Media

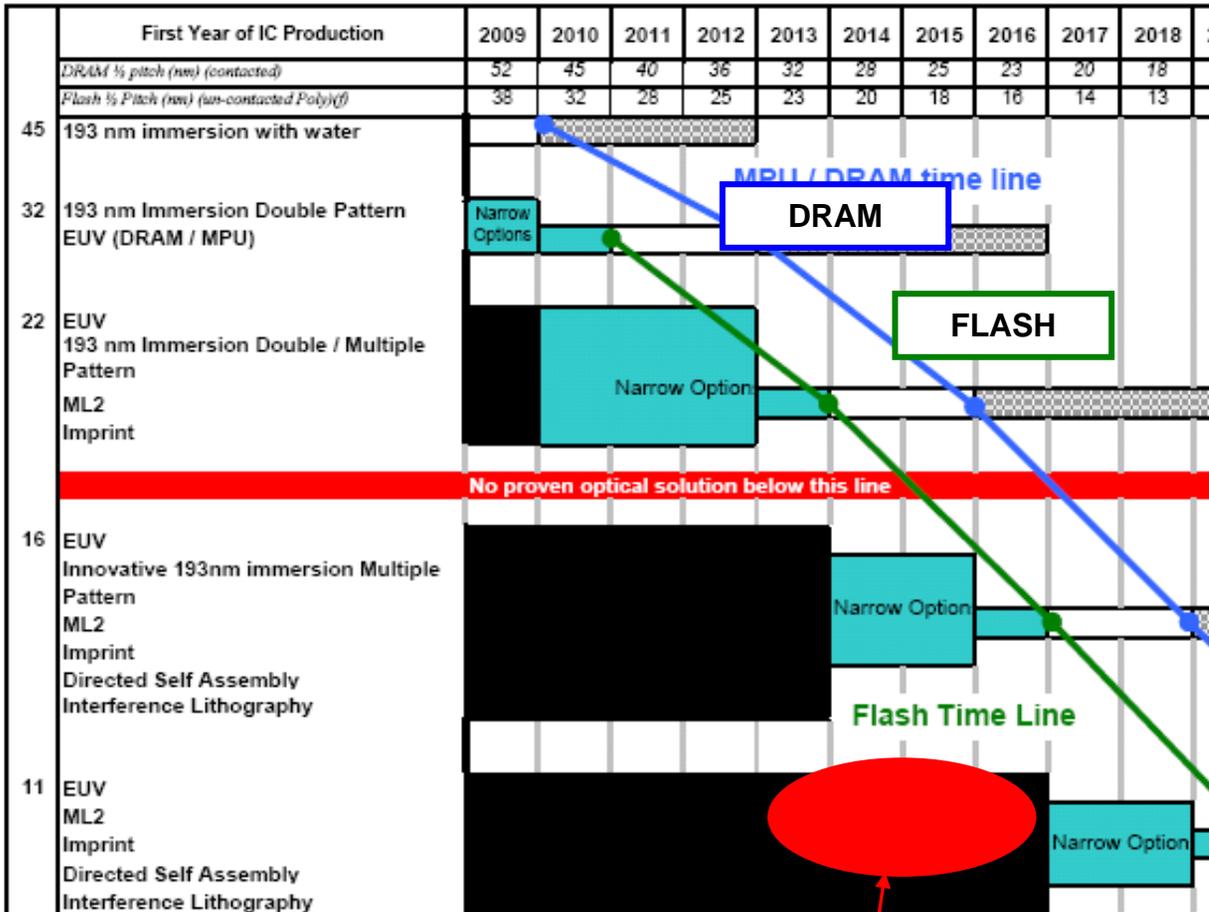
- Highly exchange coupled granular media
- Multiple grains per island, but each island is a single domain particle
- Bit locations determined by lithography
- Therm. stab. unit is 1 island (~15 nm diam.)



- The HGST patterned media fabrication plan inserts steps into traditional PMR disk process flow



Needed: A Different Roadmap



Requirements compared to semiconductor fab:

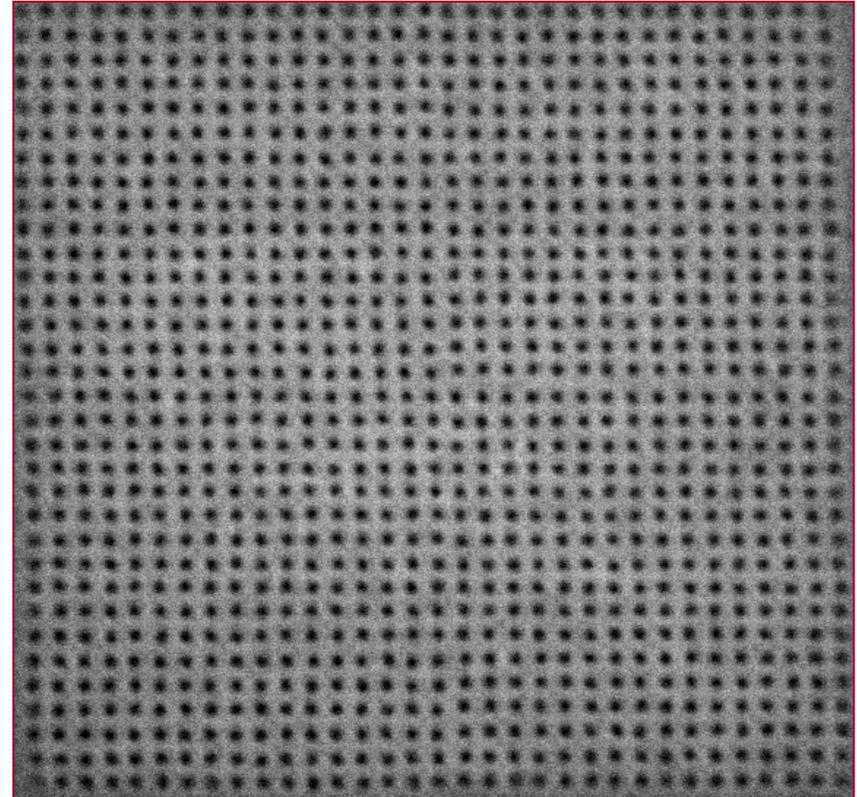
- Smaller features sooner
- Higher volume (1 billion disks/year)
- Lower cost target (< \$5/disk)
- Periodic features
- One lithography level; no overlay
- Can tolerate 1E-4 defect rate
- Can map out large defects



PATTERNED MEDIA INTRODUCTION

2009 ITRS Lithography Roadmap

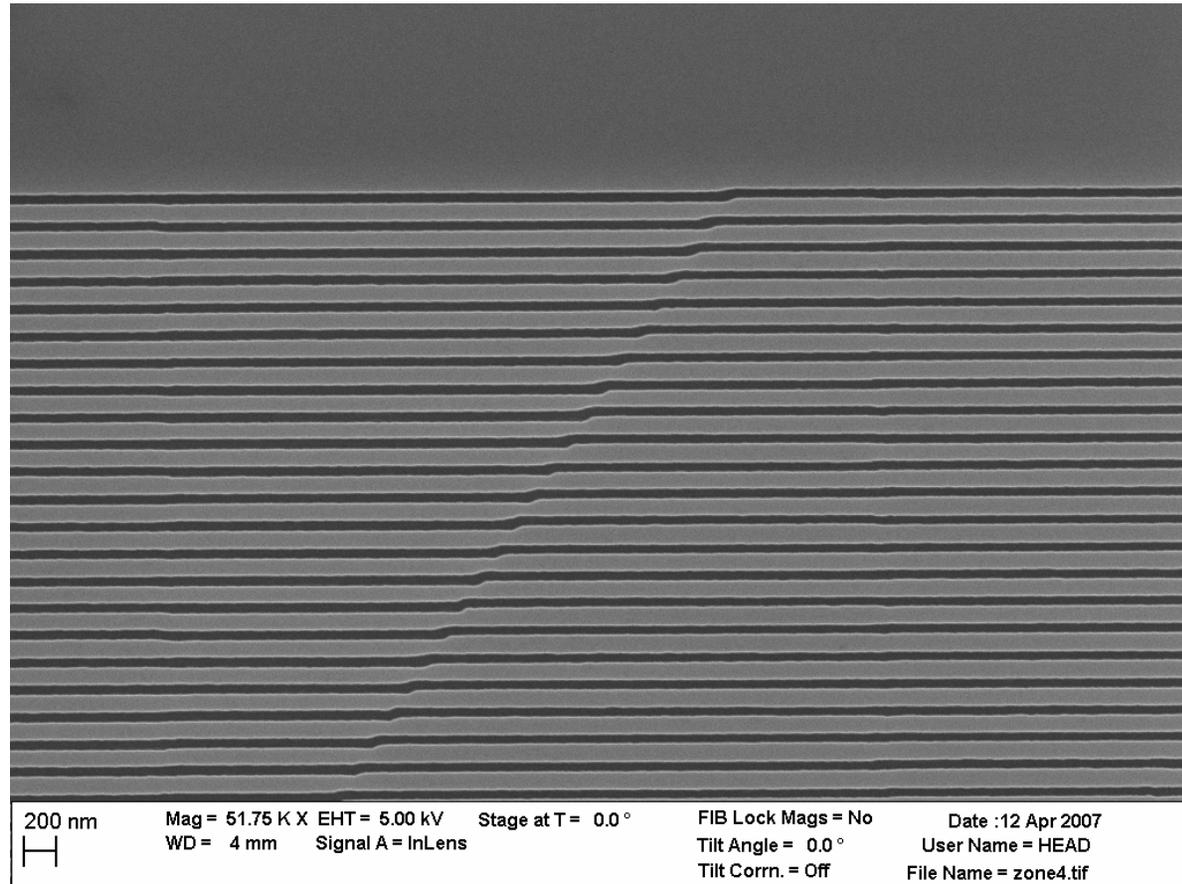
- To fabricate patterned media disks, a master pattern is first generated by e-beam lithography on fused silica substrates
- The small feature size (10–50 nm), precision tolerance requirements of 1nm 1sigma, and pattern extent require extreme measures including:
 - **Rotary-stage e-beam architecture**
 - **Cold ultrasonic development**
 - **Multiple exposures of features**
 - **Blanker-less writing**
- With e-beam write currents around 10nA and ZEP resist, writing the full 65mm disk surface can take a few days
- Ensuring low patterning defect counts with long e-beam write times over large areas is challenging

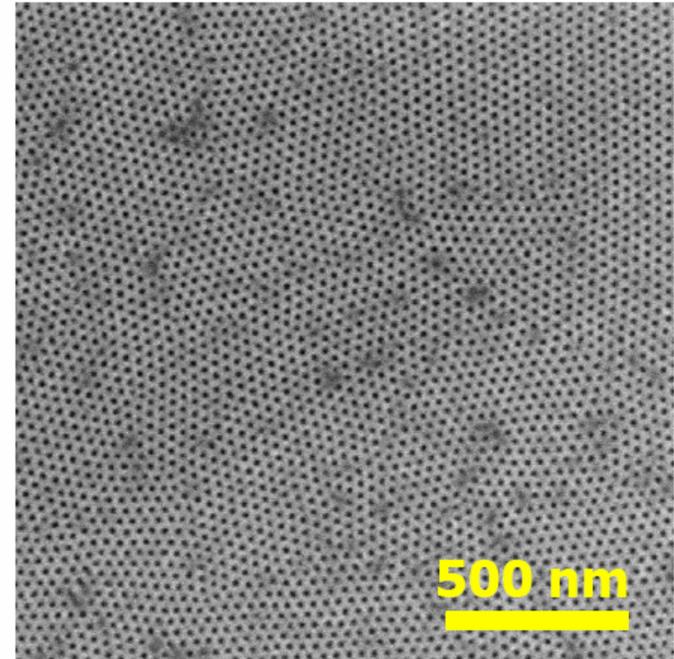
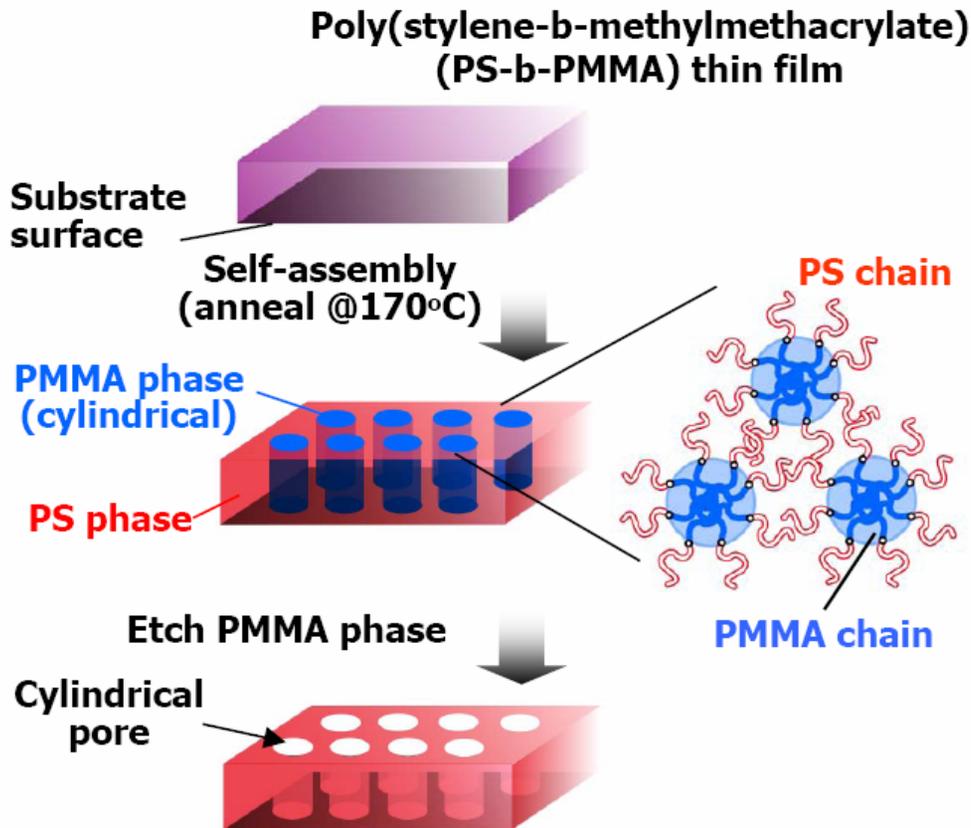


720 Gbit/in² (30 nm period):
Holes etched in Si master mold, E. Dobisz, HGST

- Field stitching errors can be seen when trying to write circular tracks with an XY positioning stage
- Typical field stitching errors are ~20nm
- BPM imprinting templates require extremely small features sizes (10-50nm) and strict position accuracy, ~1nm 1sigma
- Field stitching errors can not be compensated for with servo sectors
- To meet these demands, HGST is currently using an Elionix, 100keV, rotary stage e-beam tool

Field Stitch Defects on a Direct E-beam Write DTR Disk



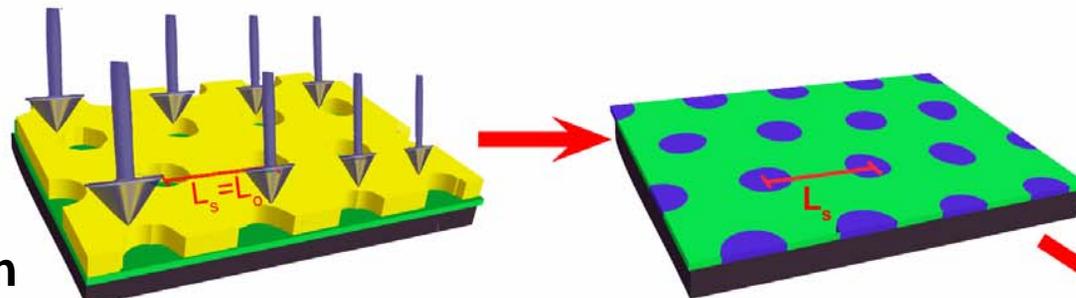


H. Yoshida – Hitachi Research Lab

- As deposited PS-b-PMMA microphase separates into short range ordered HCP
- Chemically pre-patterning the substrate with e-beam lithography allows for long range ordering

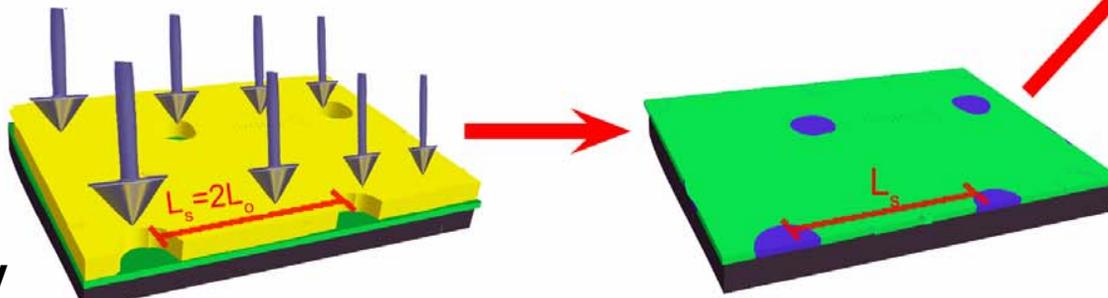
Directed Assembly for Pattern Rectification and Density Multiplication

Pattern Rectification

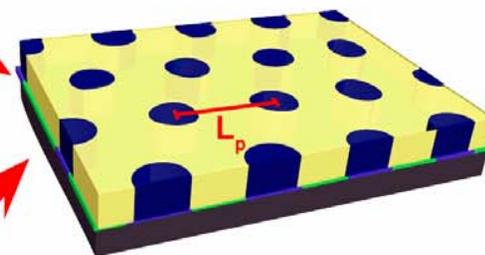


O2 plasma exposure on e-beam resist/brush

Density Multiplication



Aligned block copolymer

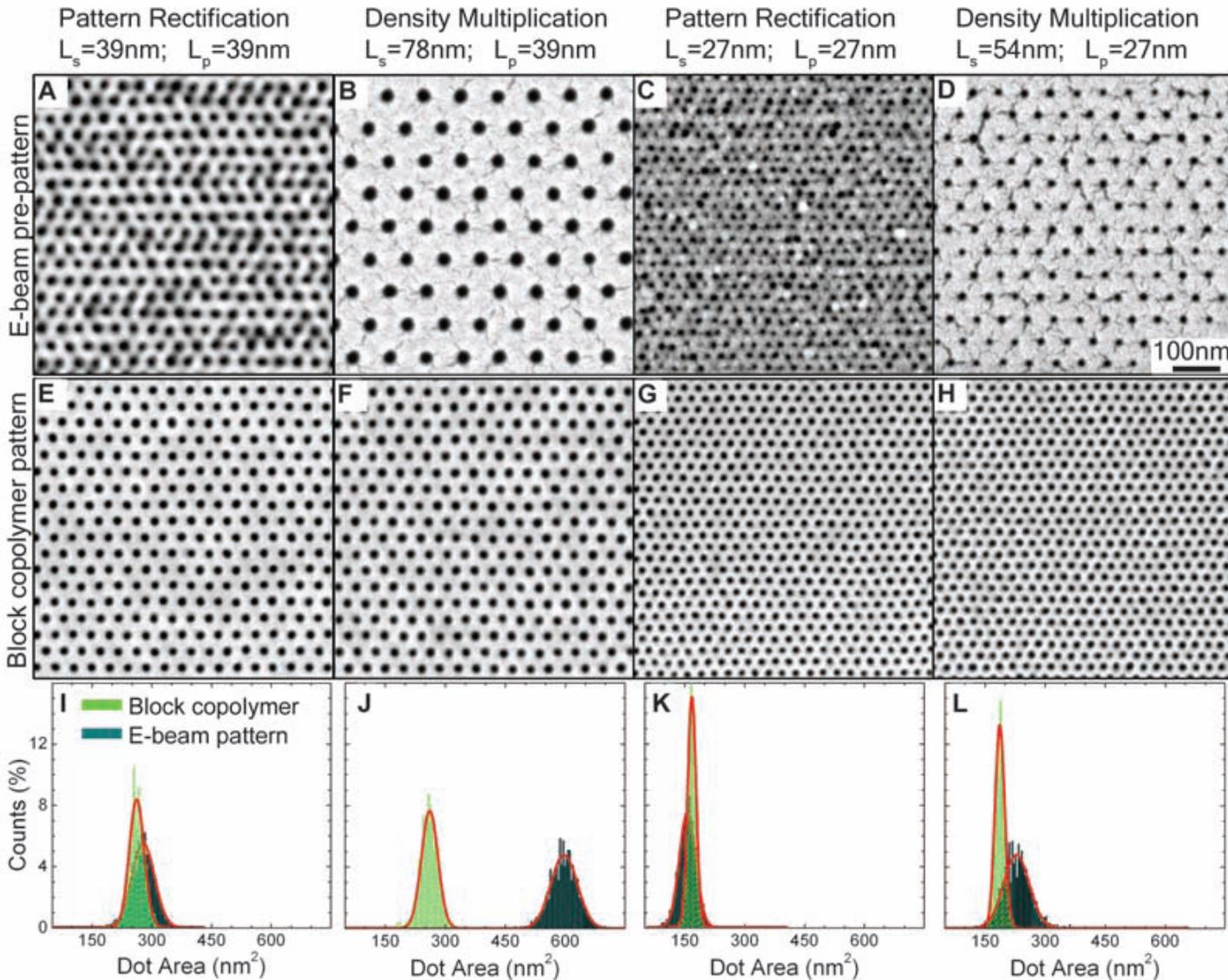


Definitions:

L_s = E-beam pattern pitch

L_o = Block copolymer natural pitch

L_p = Block copolymer pitch on top of chemical pattern



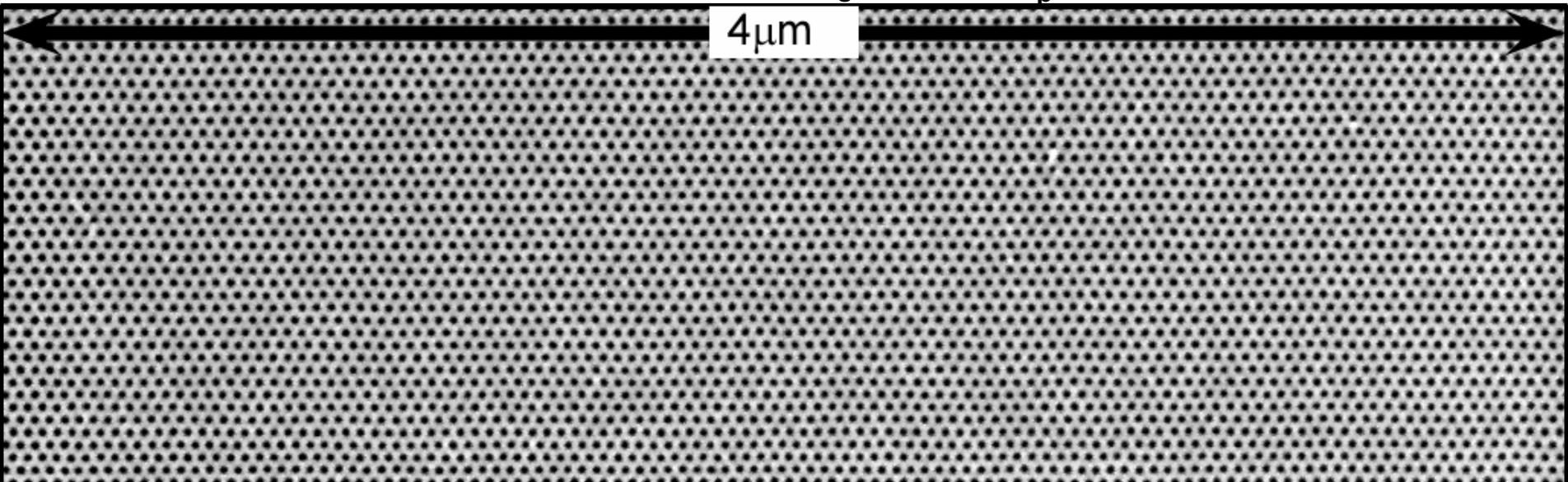
R. Ruiz, E. Dobisz, D. Kercher – HGST

H. Kang, P. Nealy – Univ. Wisconsin

Dot Size Distribution

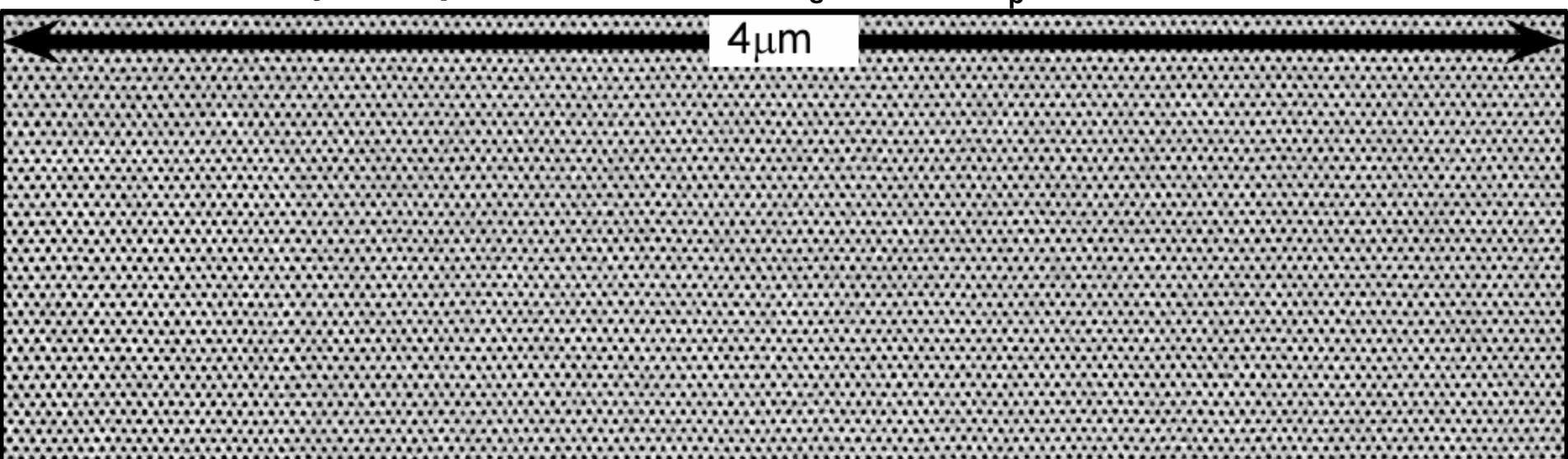
Density multiplication. 490Gb/in² $L_s=78\text{nm}$; $L_p=39\text{nm}$

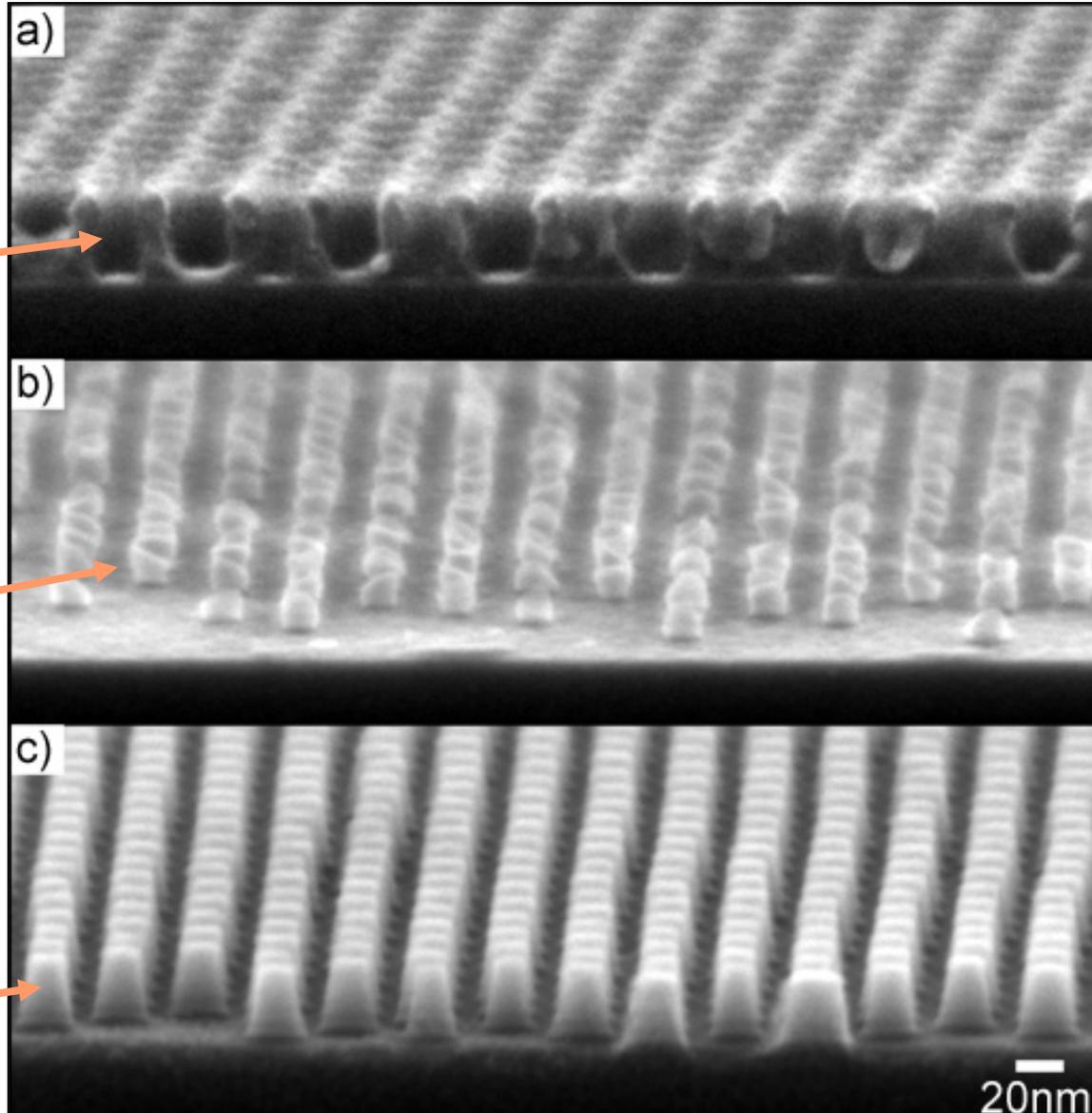
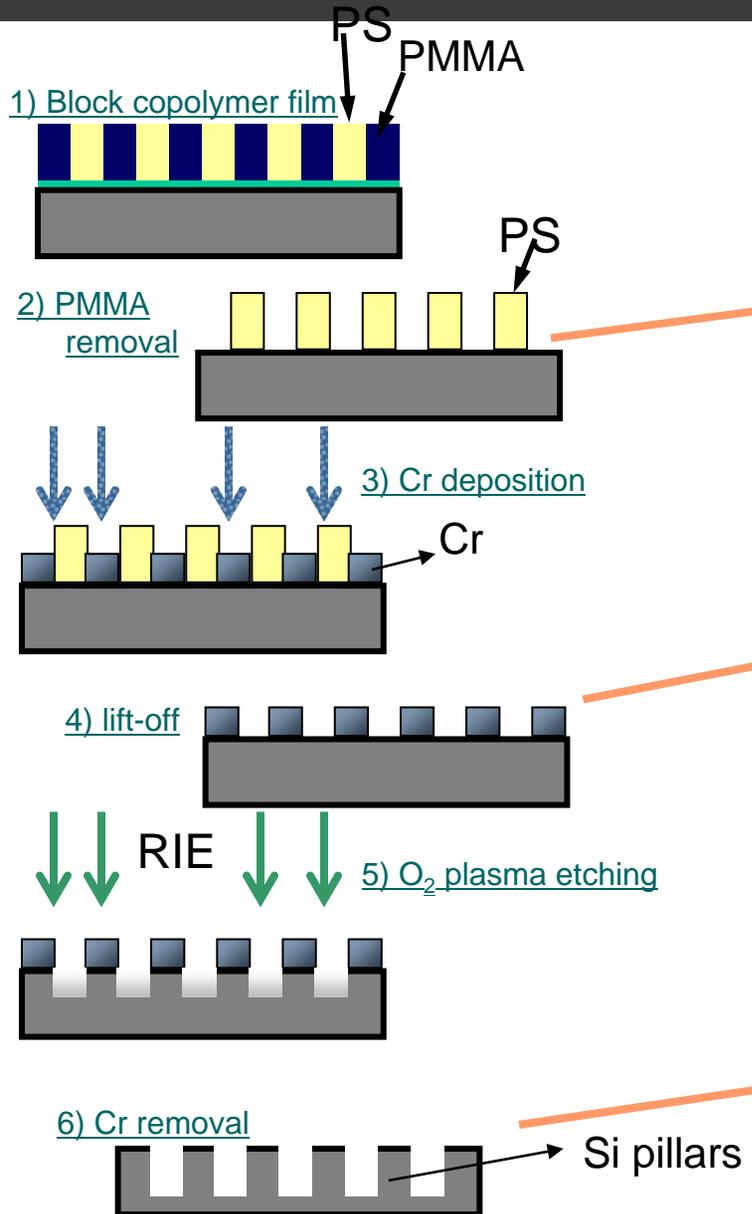
4 μm



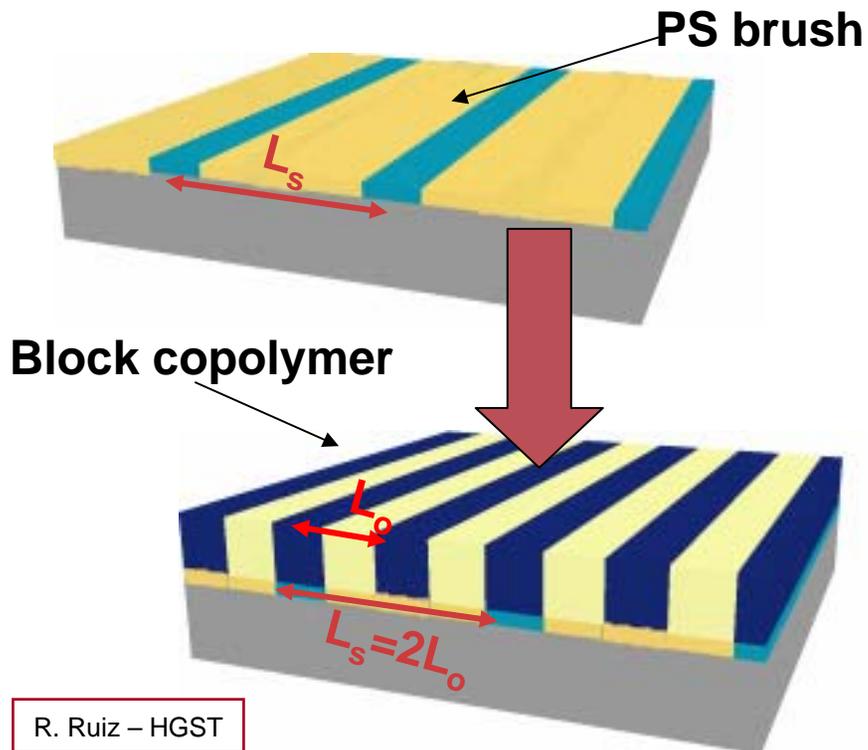
Density multiplication. 1Tb/in² $L_s=54\text{nm}$; $L_p=27\text{nm}$

4 μm

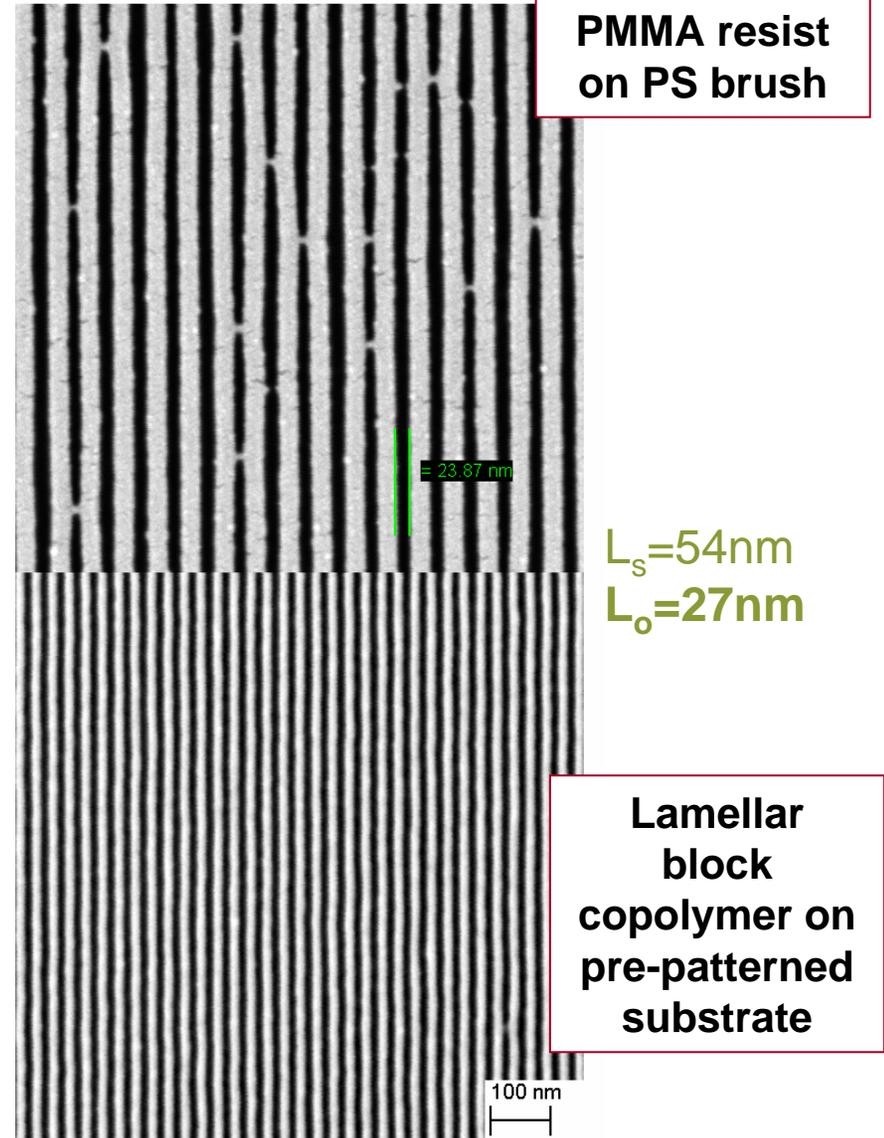




- Line and space pattern density multiplication, suitable for DTM, has been demonstrated
- 27nm pitch lines from a 54nm pitch e-beam pattern



R. Ruiz – HGST

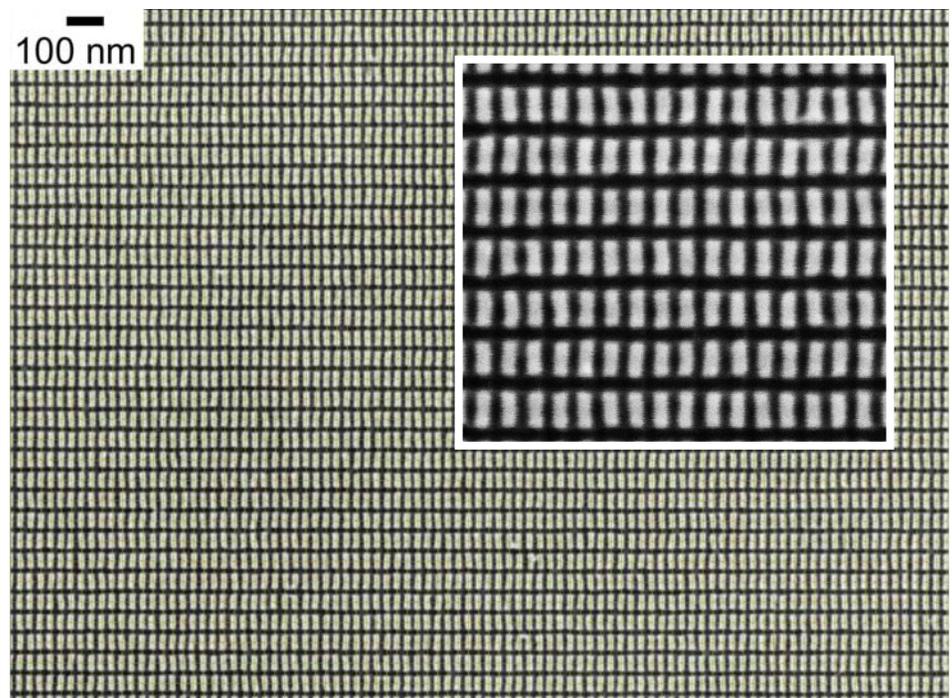


BAR=2

Down-track Pitch=27nm

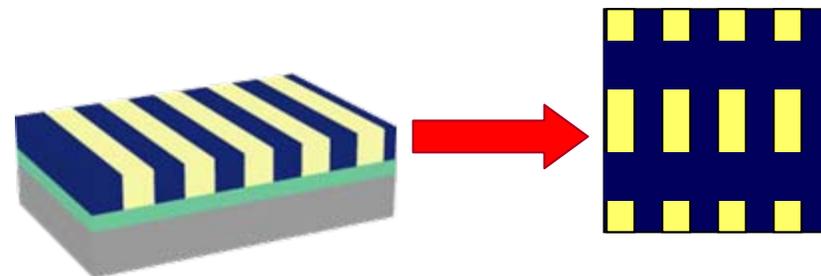
Track pitch = 54nm

Density: 442Gdot/in²



Skewed patterns also straightforward by this method

Lamellar phase block copolymers for high bit aspect ratio



200 nm
H

Mag = 50.00 K X

EHT = 1.00 kV

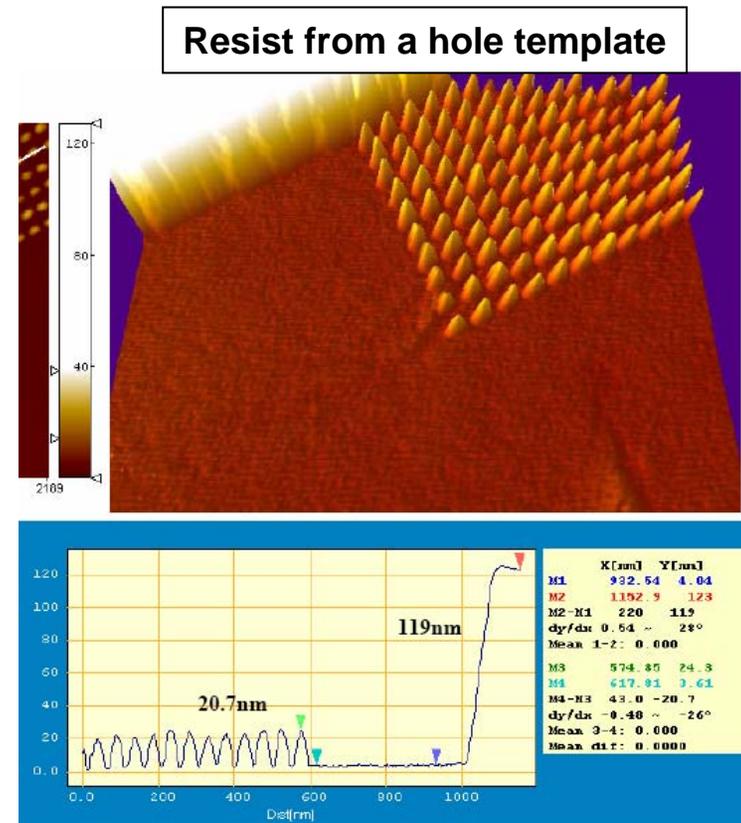
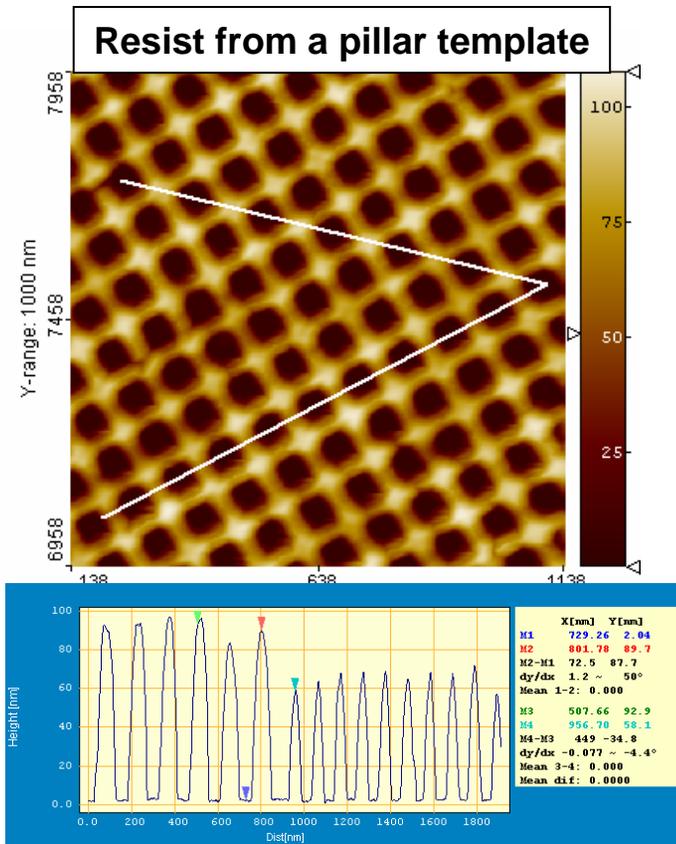
Stage at T = 0.0 °

WD = 3 mm

Signal A = InLens

U.S. patent application US20090308837A1, published 12/17/09

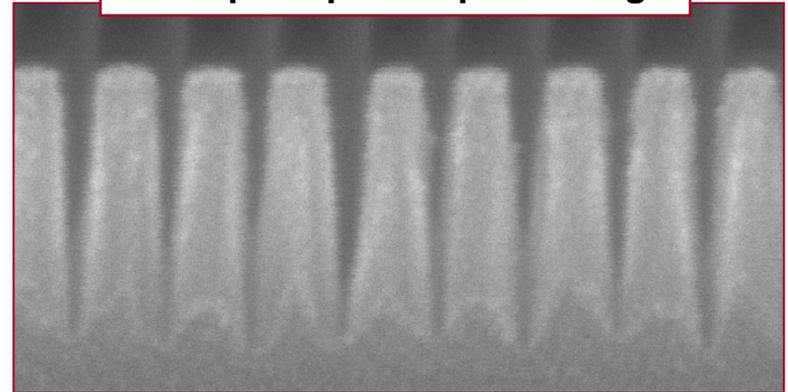
- When dry etching nano-imprint templates our initial process resulted in large etch rate differences depending on feature size
- This is caused by various problems including RIE lag and ion scattering



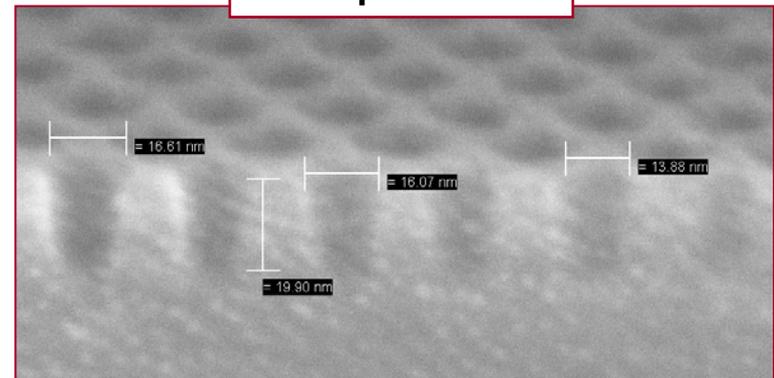
35nm pitch patterns in nano-imprint resist

- Even though very high aspect ratio structures can be achieved, they are not useful for the nano-imprint process
 - 2:1 aspect ratio or lower is ideal
- With a properly selected SiO₂ etch recipe, vertical sidewall and flat etched trench bottoms can be achieved at 14nm half pitch

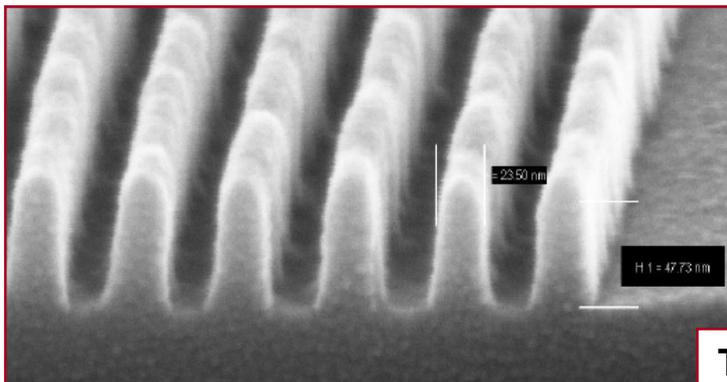
35nm pitch pillars: poor design



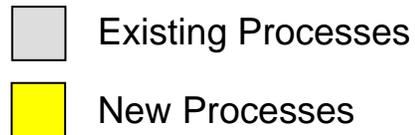
27nm pitch holes



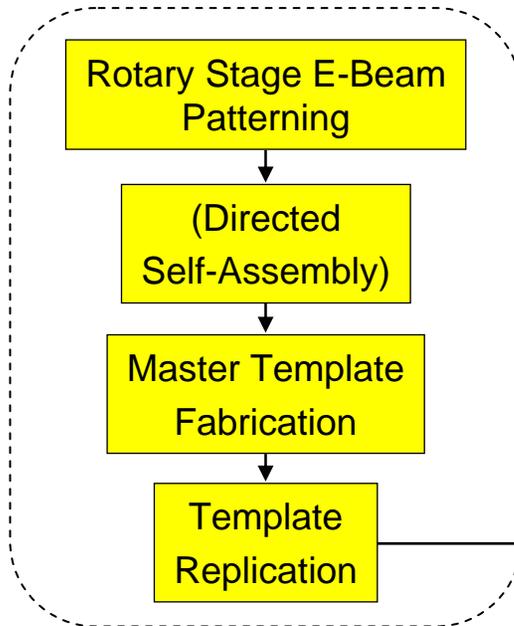
48nm pitch lines, Cr hard mask remaining



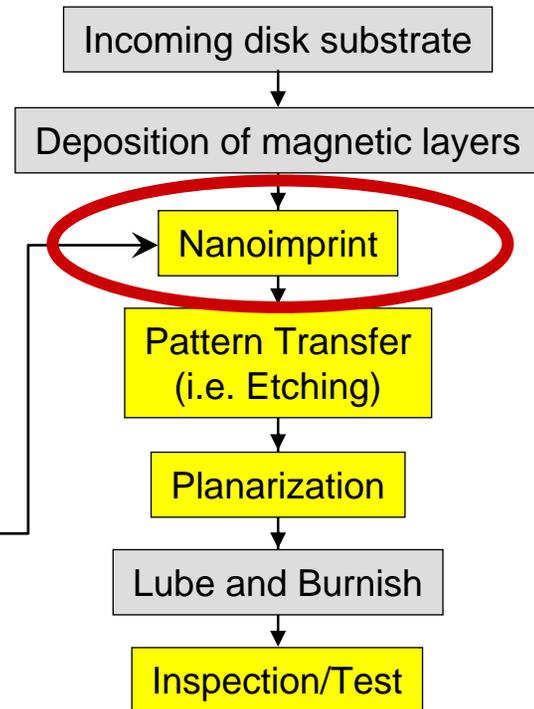
T. Hirano, K C Patel



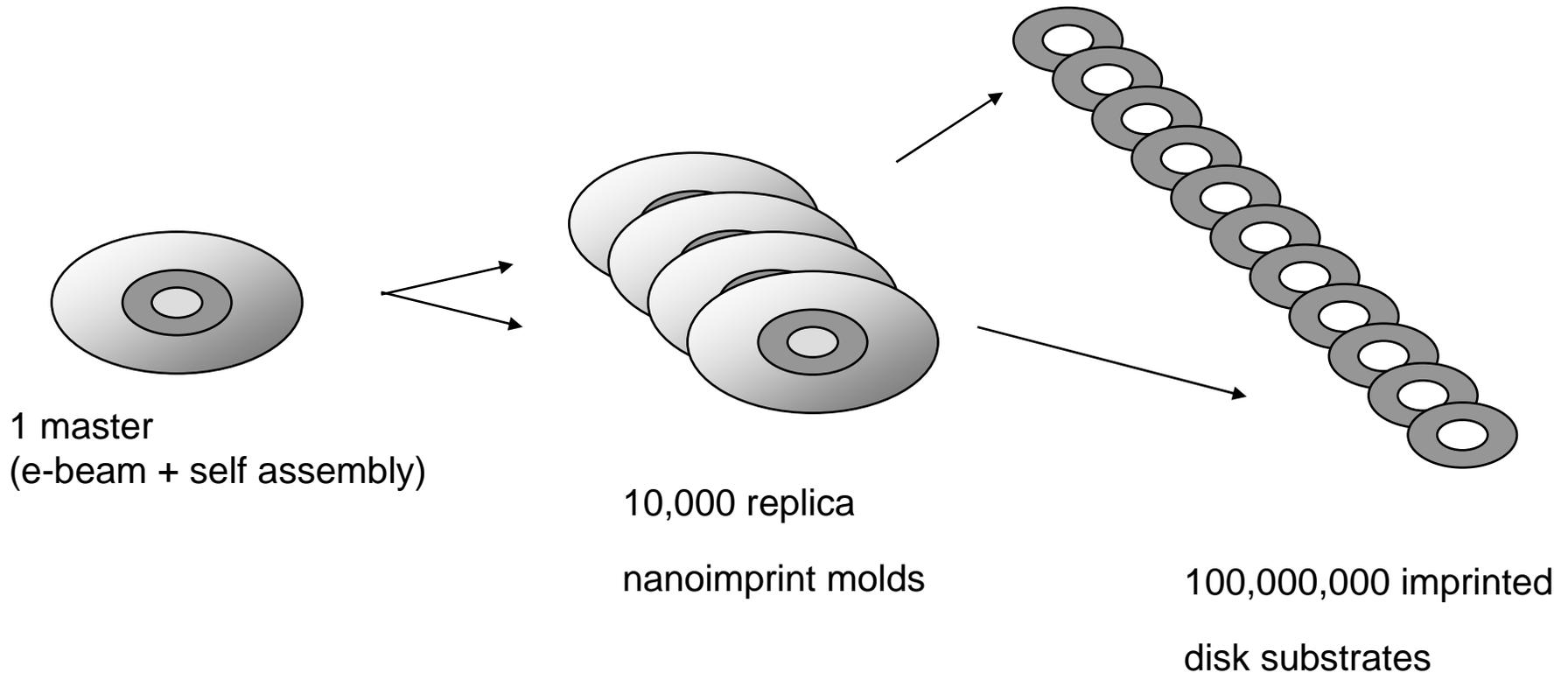
Template Fabrication



Media Fabrication Process



- **E-beam master will be expensive (many days to write on master pattern)**
- **Two generation nanoimprinting process envisioned for low-cost replication**

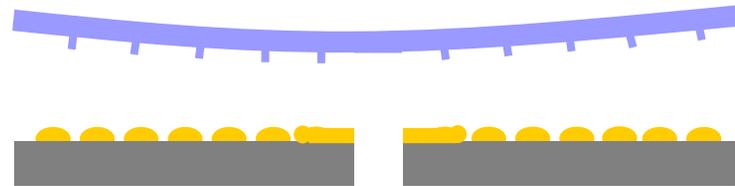


Graphic: MII

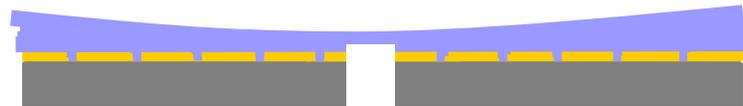
- Resist dispensing (ink jet)



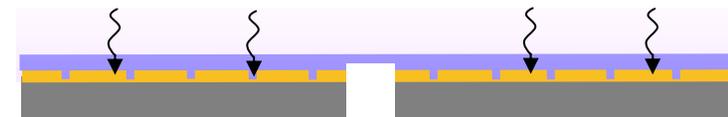
- Thin template is bowed so initial contact in the center of the disk



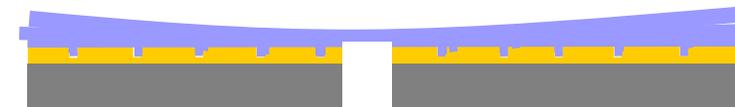
- Capillary forces pull template into conformal contact with the disk



- Expose with UV light to cure the imprint resist

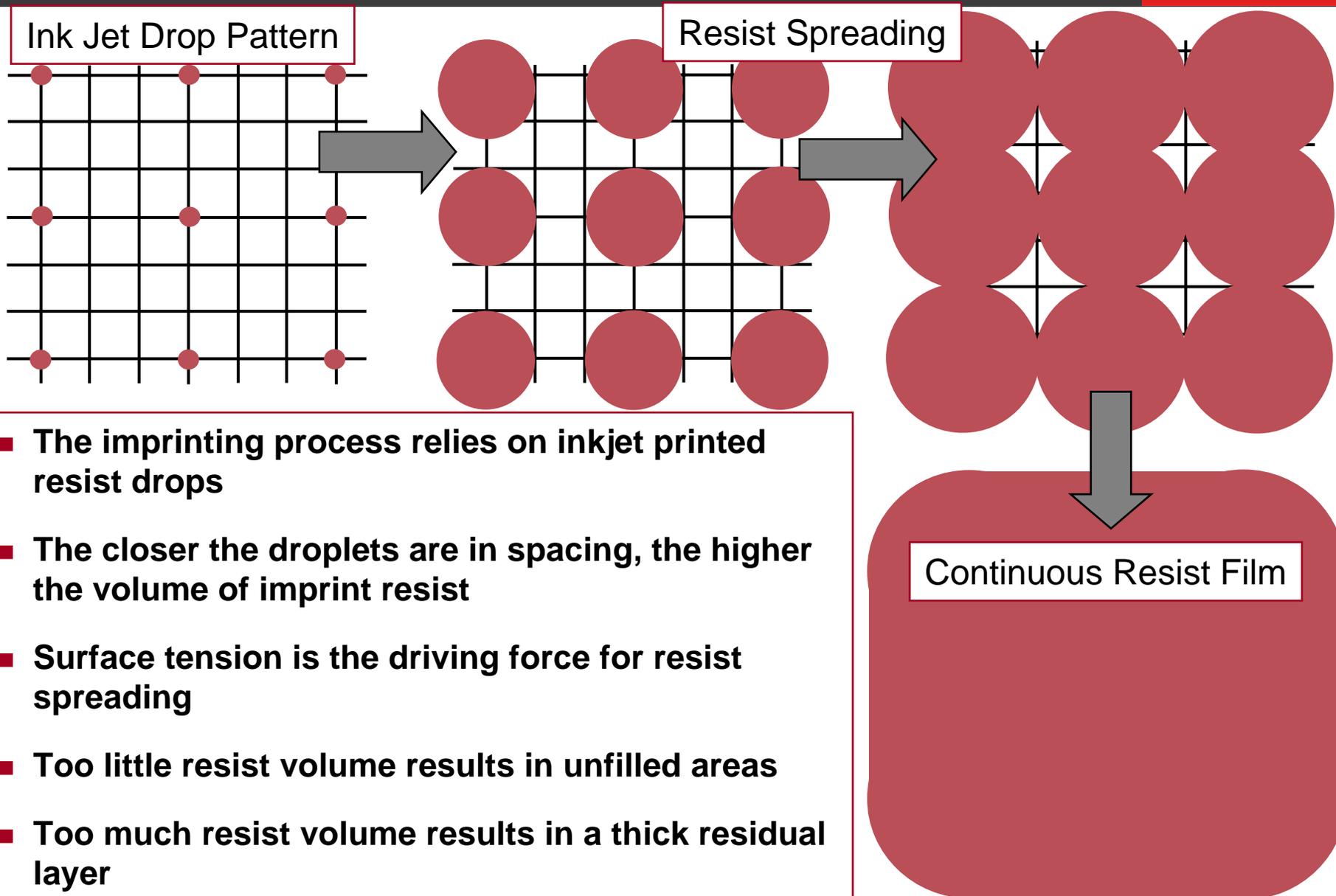


- Separate template from disk



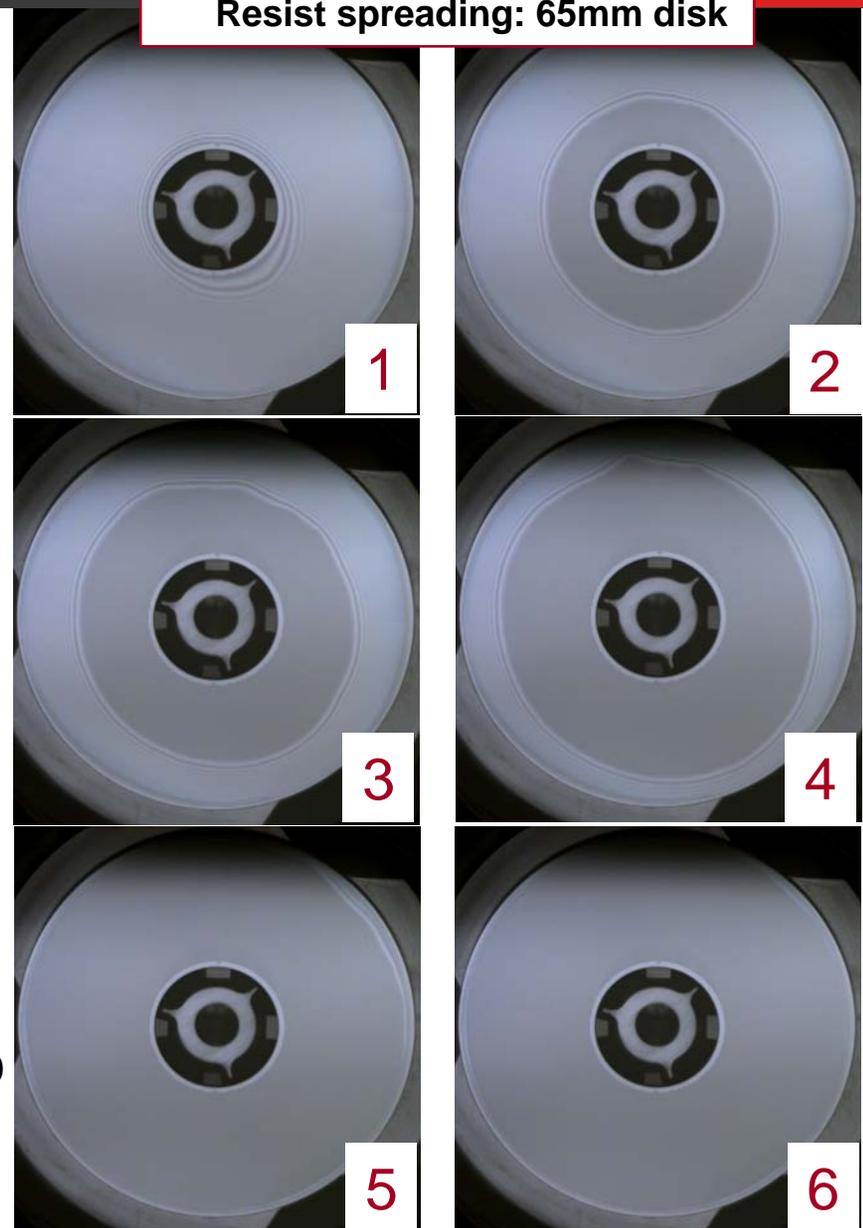
- Etch

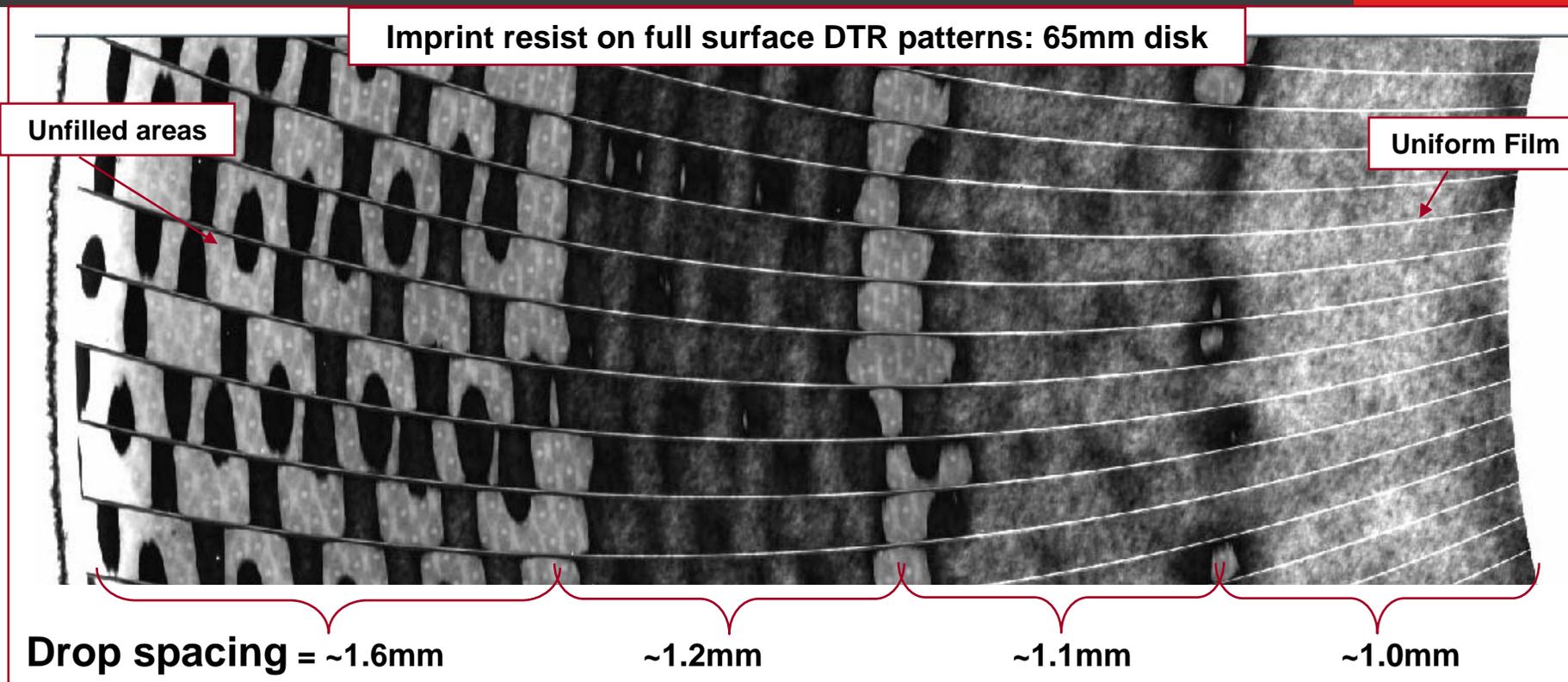




Resist spreading: 65mm disk

- **65mm disk imprinting: one step process with no overlay requirements**
- **Hard imprint templates are preferred (fused silica)**
 - Long lifetime
 - No feature deformation during imprinting
 - Easily cleaned if contaminated
- **Template is coated with a release agent**
- **Disks are coated with an adhesion promoter**
- **Resist dispensed with ink-jet printer**
- **Fast spreading is important for high throughput**
- **Proper design is required to ensure that excess resist does not build up at the OD and ID of the disk**

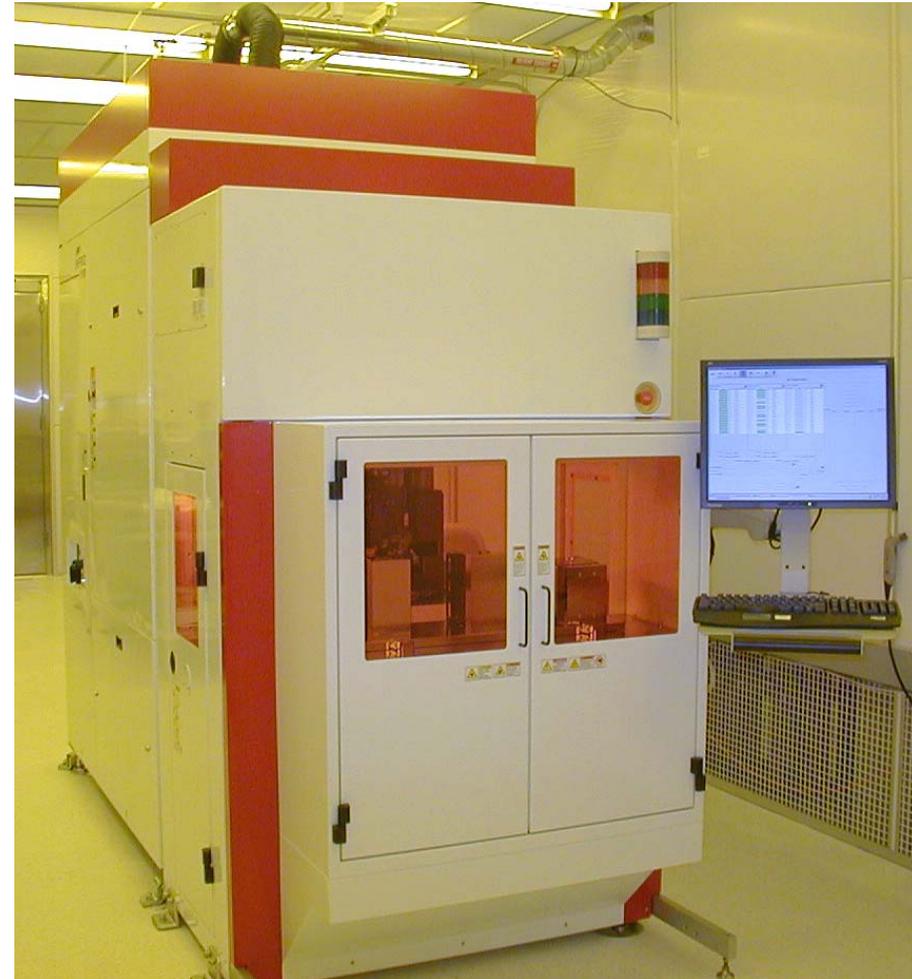




- Candela images show the spreading of imprint resist with a DTR template for various ink-jet dispense droplet spacing
- For this particular DTR imprint template, resist drops spaced too far apart (>1.2mm spacing) will not form a continuous resist film
- Resist drops at 1.1mm spacing show some variation in thickness

NIL Requirements

- High disk throughput ~800dph
 - Parallel processing of disks may be required to keep pace with sputtering equipment
- Double side imprinting
- Fast spreading of the imprint resist
- Thin resist residual layer thickness [RLT]
- Excellent resist filling in small features with no unfilled areas
 - Low viscosity polymer
- Low particle defects on disks
 - Very clean incoming substrates
 - Good adhesion and release properties
- Clean imprint templates



Molecular Imprints, Imprio 1100, first generation single side disk imprinter, ~20dph, installed in 2007

MII Imprio 2200 NIL Tool

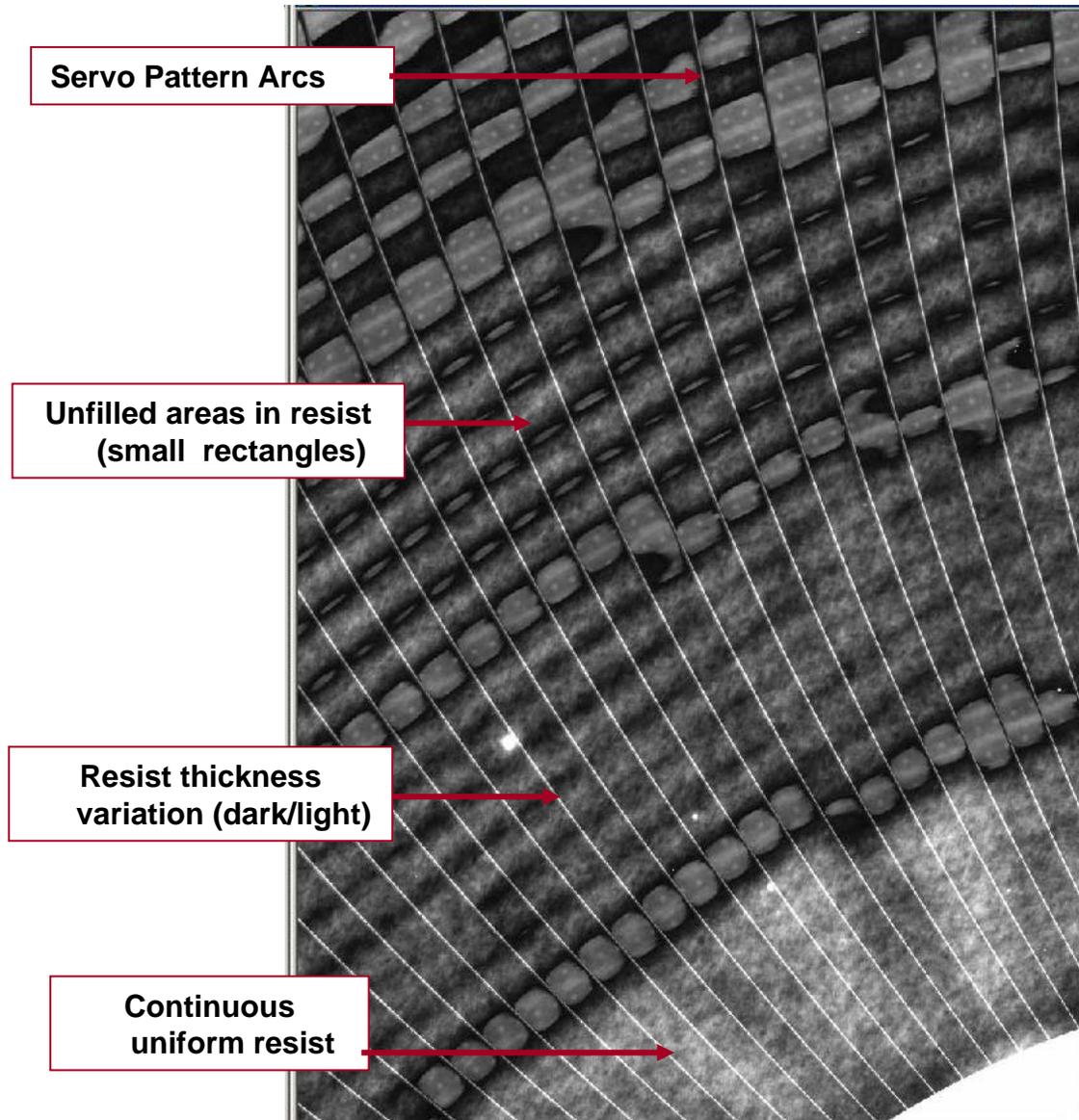


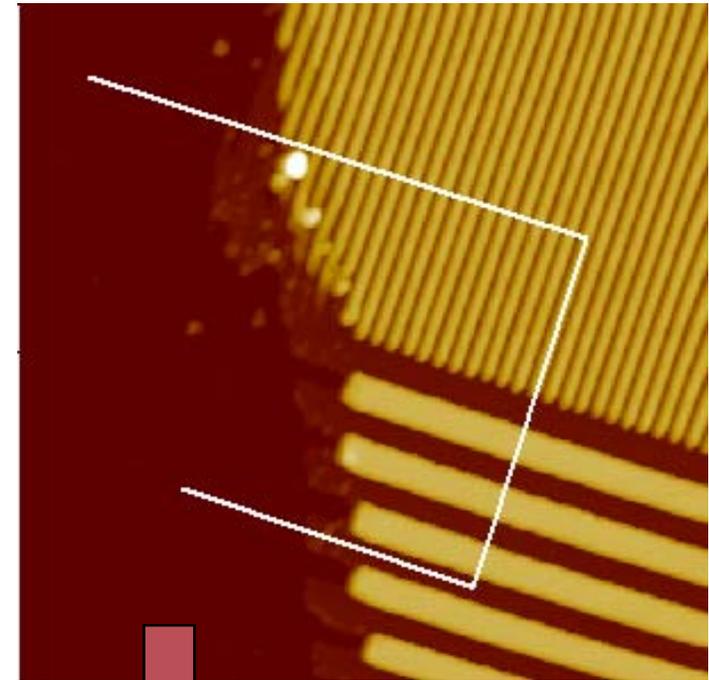
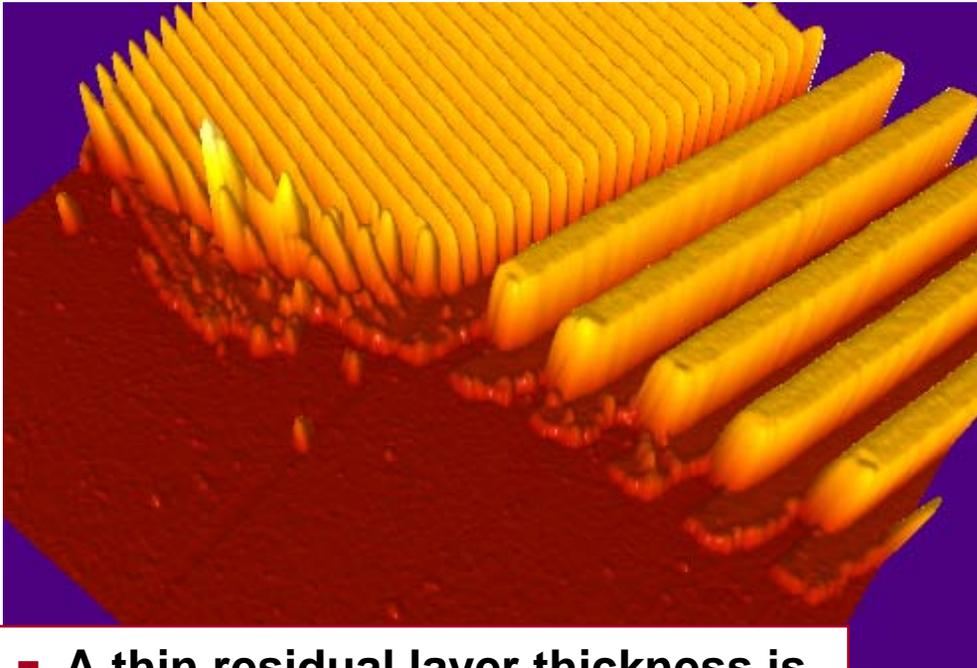
180dph double side disk imprinting system, installed at YB in 2009



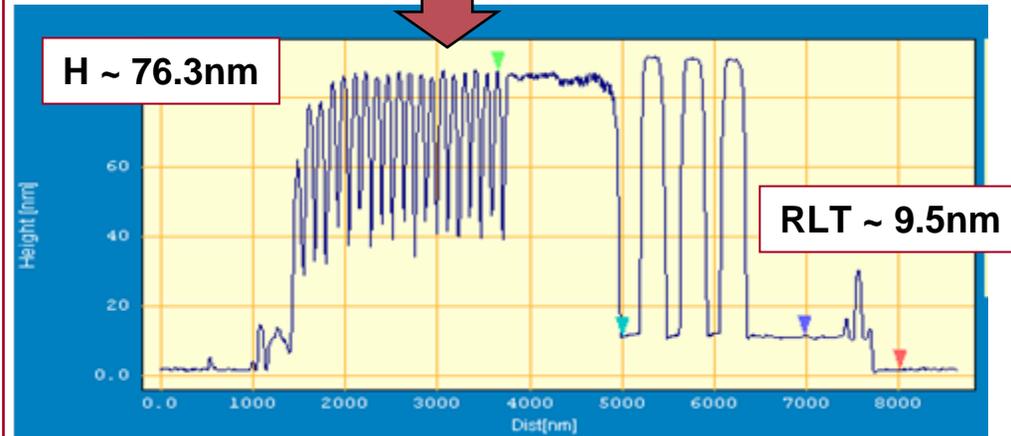
300dph double side disk imprinting system, installed at Cottle Rd in 2010

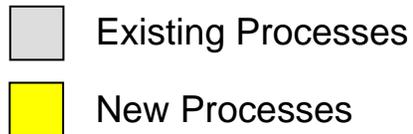
- In a DTR nano-imprint template, the majority of patterns are circumferential grooves (data tracks)
- This Candela image shows the resist flow for various ink jet drop patterns
- After spreading, the unfilled areas are thin rectangles oriented along the tracks
- The resist prefers to flow along the template track grooves
- Understanding resist flow is important when creating an ink jet drop pattern for a template



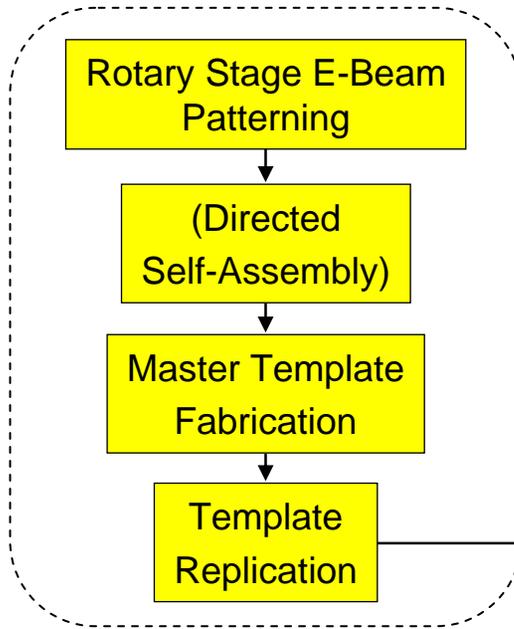


- A thin residual layer thickness is required for pattern transfer purposes
- AFM measurement along a scratch on the imprinted resist can measure the RLT
- With the appropriate ink jet dispense pattern, RLT can be kept below 10nm

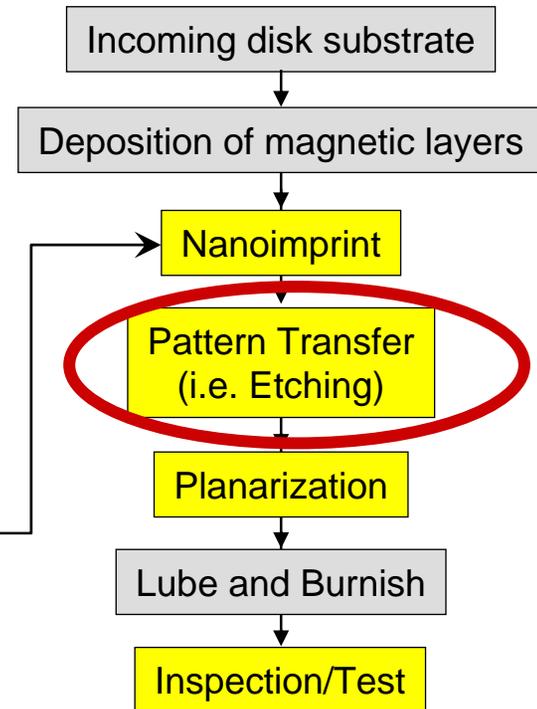


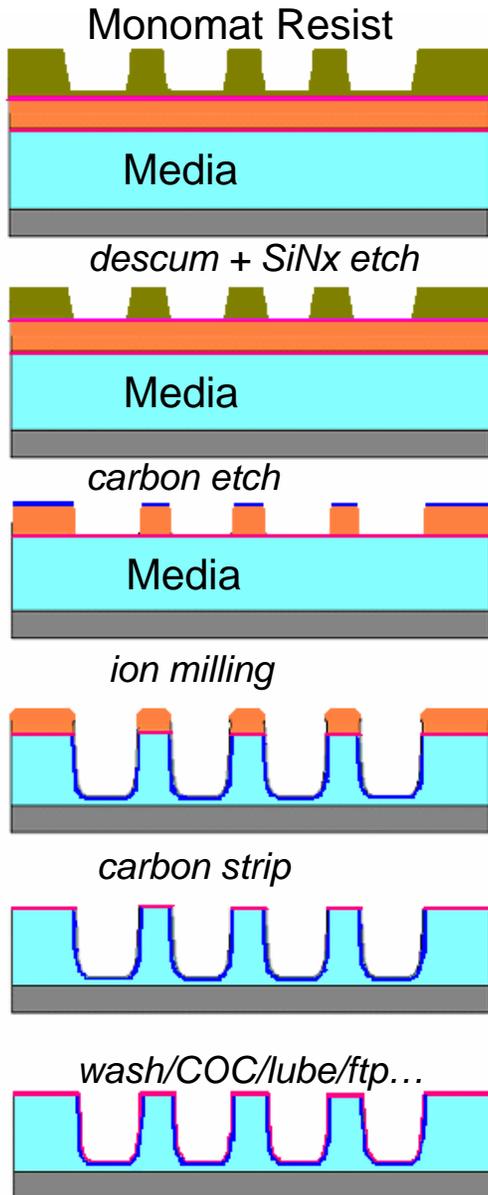


Template Fabrication

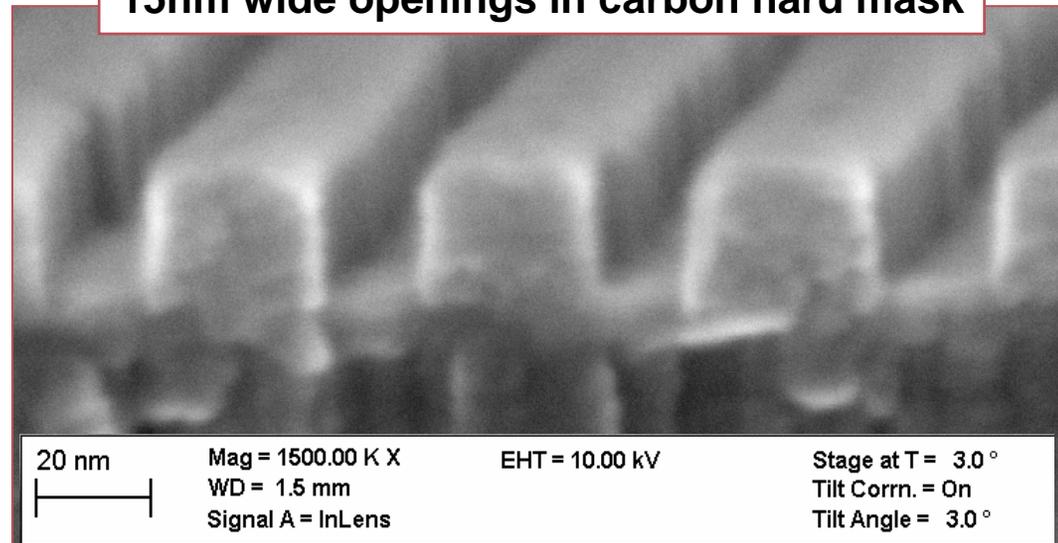


Media Fabrication Process



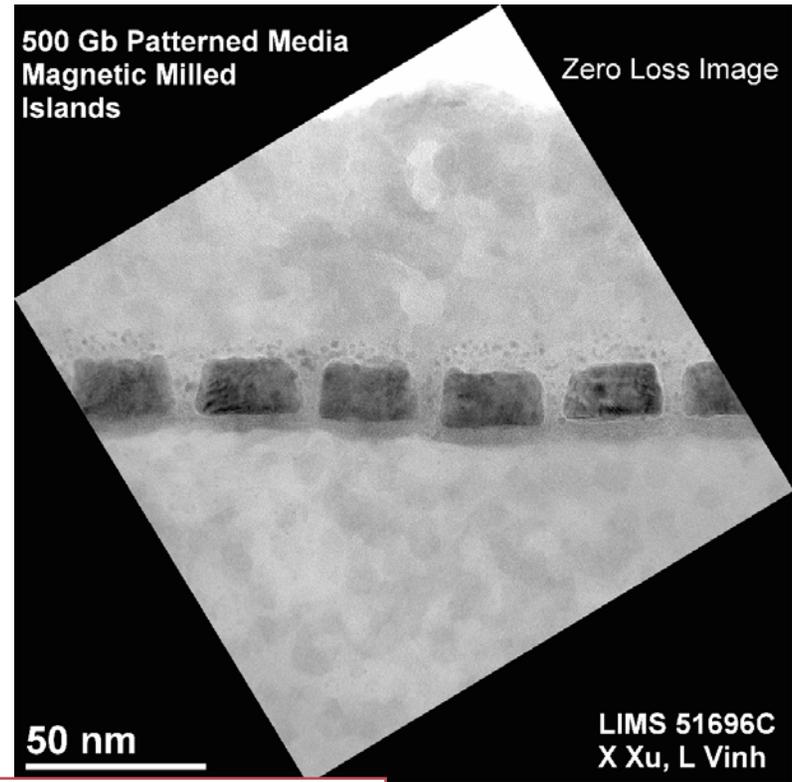
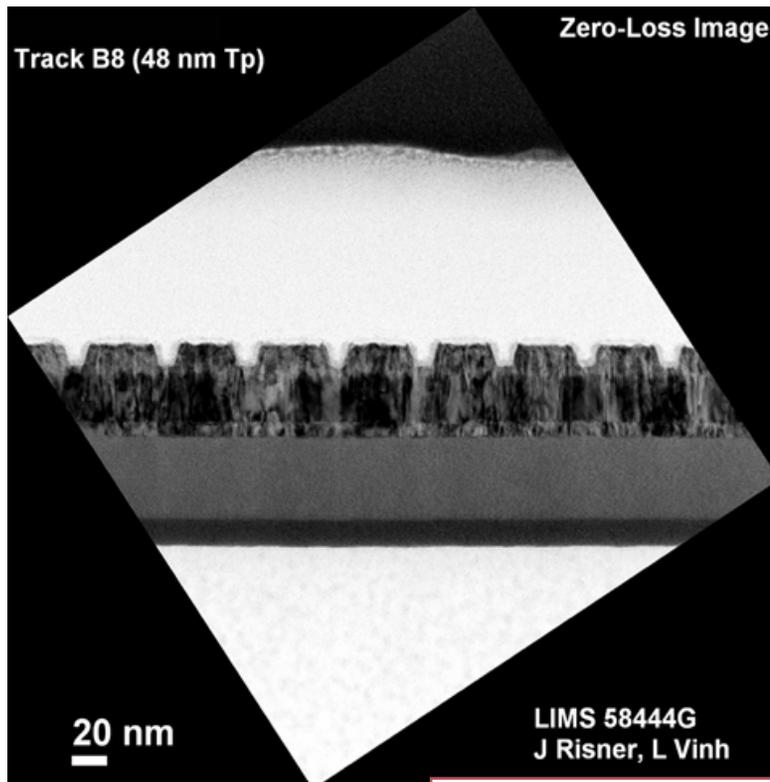


15nm wide openings in carbon hard mask

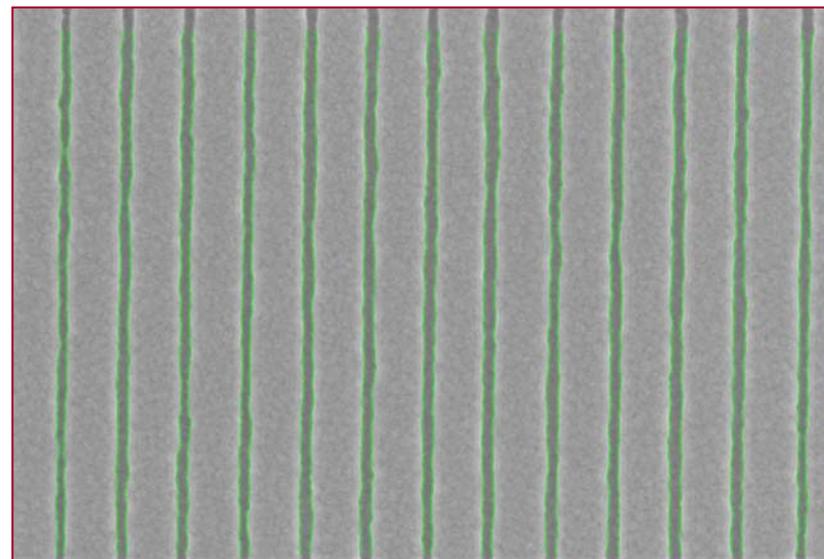
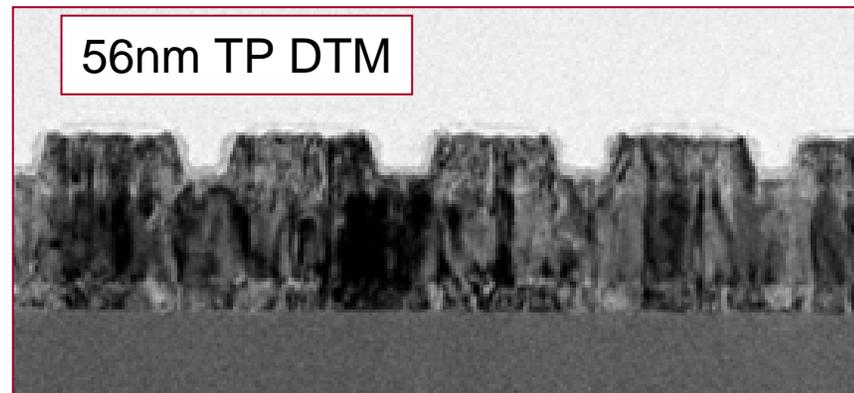
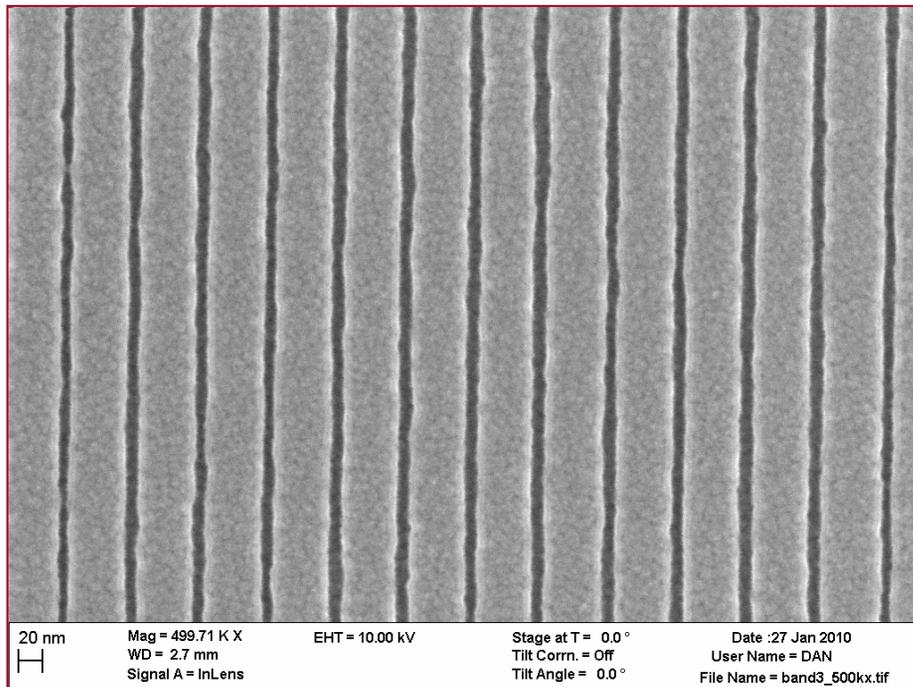


- The media etch process flow transfers the imprinted pattern into a carbon hard mask
- A CO₂ plasma etch for Carbon hard masks can produce very vertical wall angles
- Carbon is the best material choice as an ion milling hard mask due to its low sputter yield
- After the media etch and hard mask strip, a final carbon overcoat is deposited to stop corrosion

- Magnetic materials can not be etched with a reactive process
- Ar ion beam etching, or sputter etching, is used to transfer the image into magnetic films
- Both tracks and dot patterns can be etched



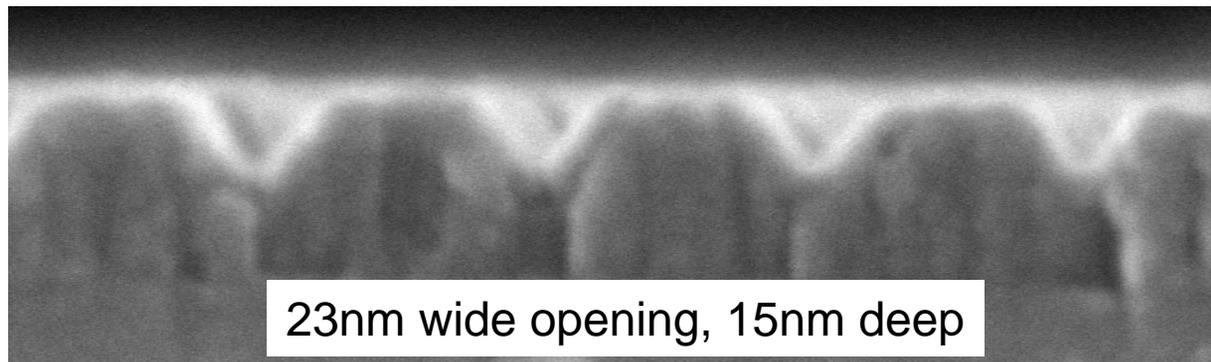
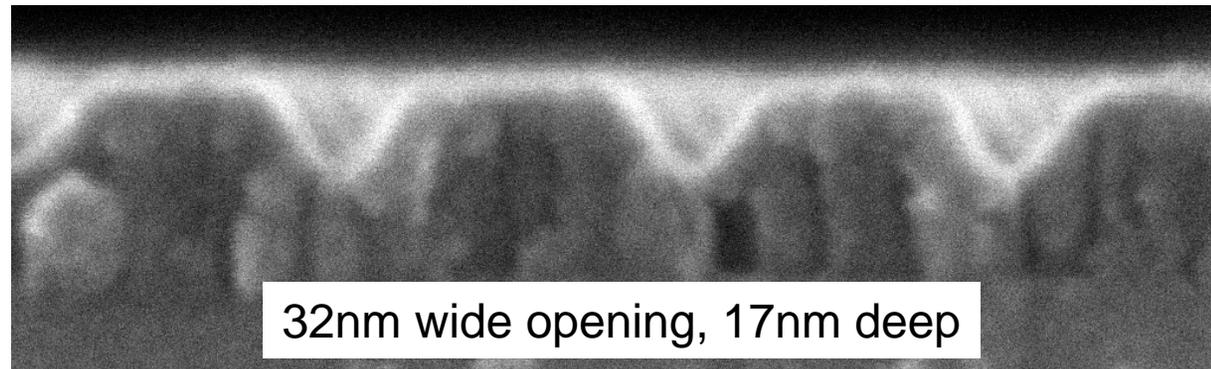
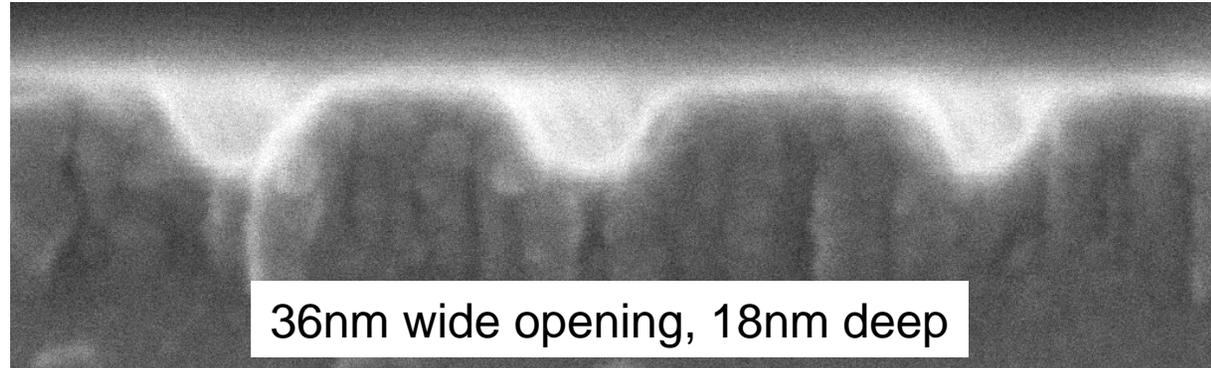
TEM images of etch magnetic films

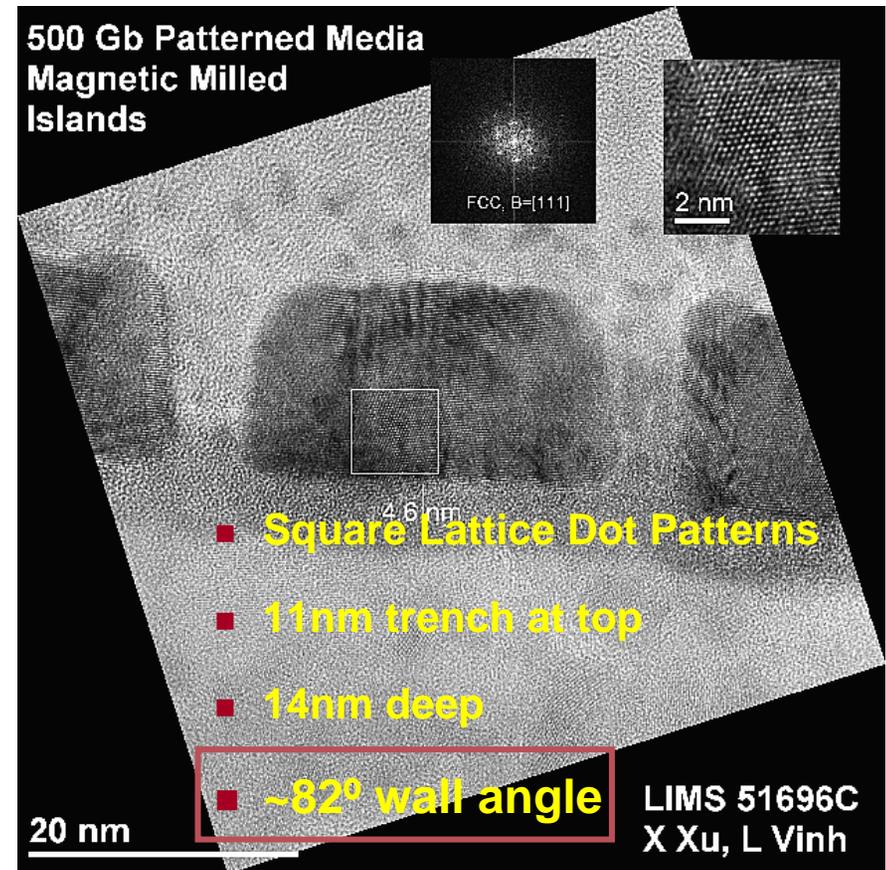
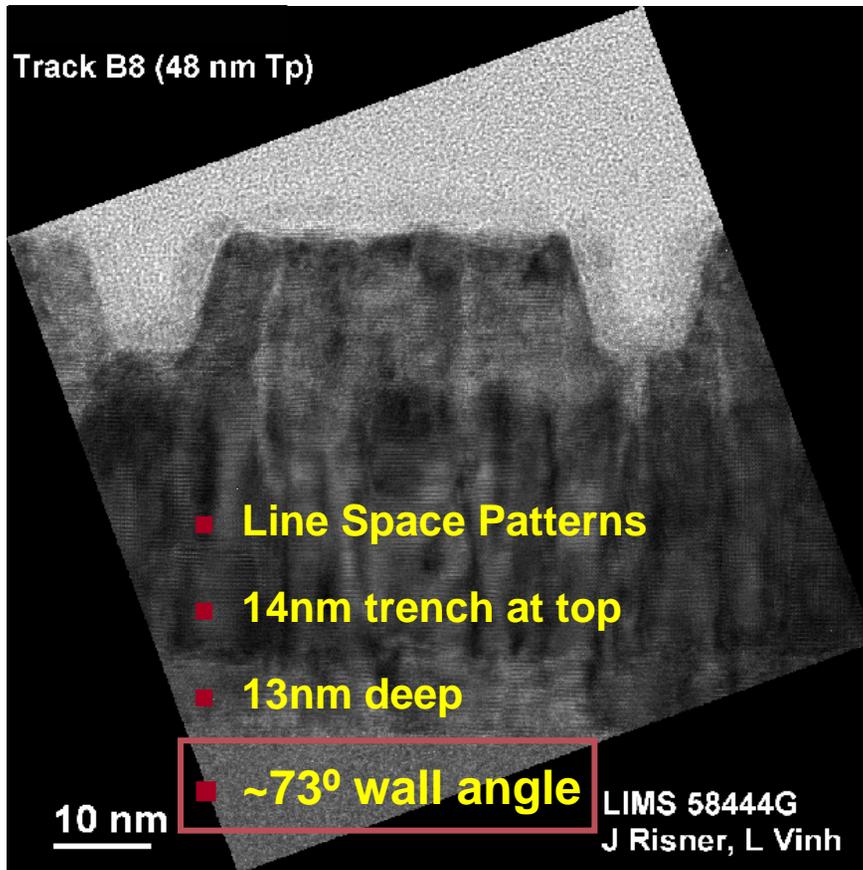


LER: 2.3 nm 3σ LWR: 3.5 nm 3σ

- Pattern transfer from nano-imprinted resist can result in very well defined magnetic patterns
- LER less than 1nm at 1 sigma

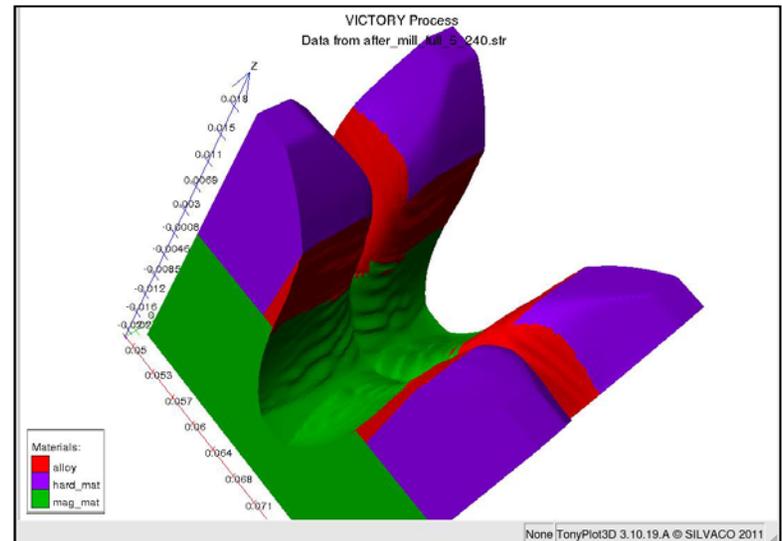
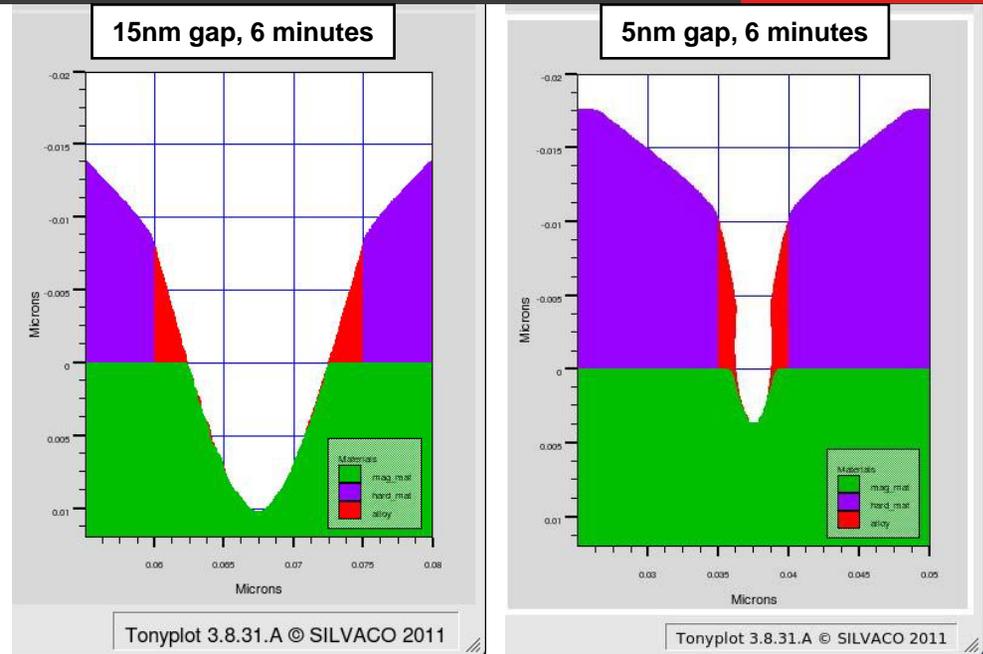
- Experiments have shown some limitations of our process when ion beam etching narrow features
- The etch front appears to pinch off for smaller features
- SEM images show 36, 32, and 23nm grooves all etched on the same disk



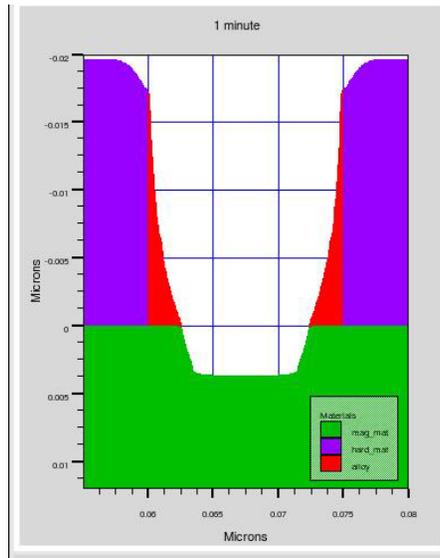


- Line/Space patterns, with less solid angle for etch material to escape, have shallower sidewall angles

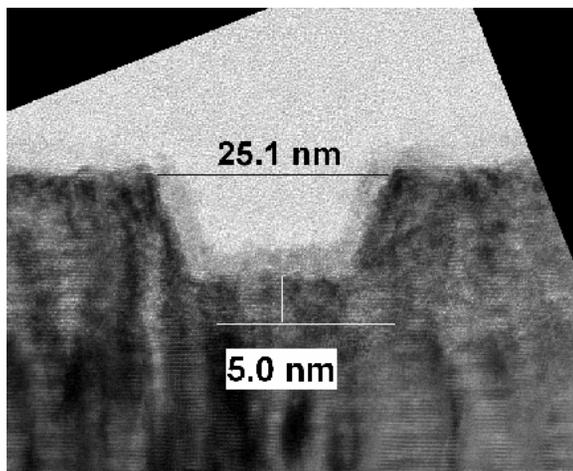
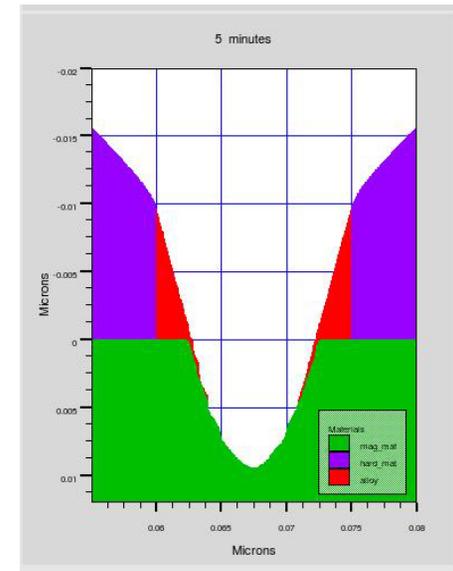
- A patterned media type Monte Carlo simulation was run using the Silvaco Victory Etch package
- The simulation shows the etching of magnetic bits with a carbon hard mask
- Two different bit spacings were investigated in the same simulation run
- When considering beam tilt, rotation, beam divergence, and mask erosion, there is significant pinch-off for small dimensional features



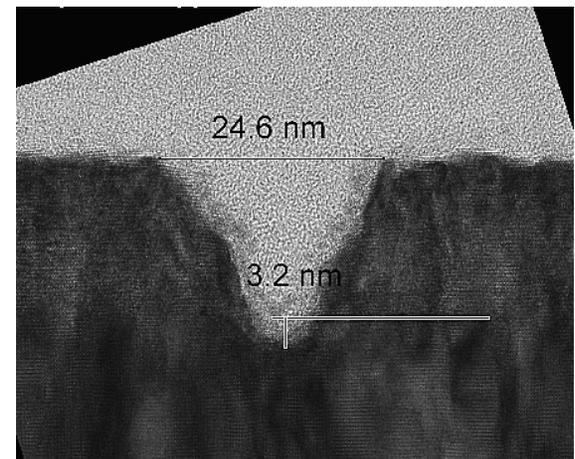
- As the etch time increases, the rate decreases and the flat etch bottom is lost



**Simulation: 15nm groove
t = 1min → 5min**



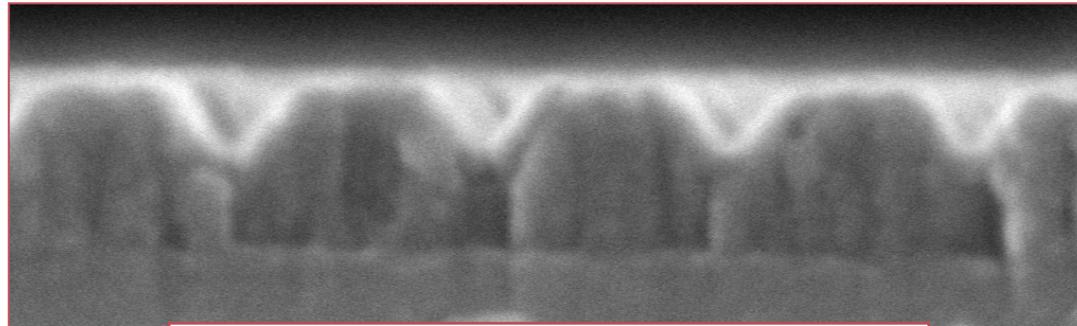
**DTR Tracks: 25nm groove
t = 2min → 5min**



- **Narrow etched grooves show shallow etch depth: all images at t = 5min mill**



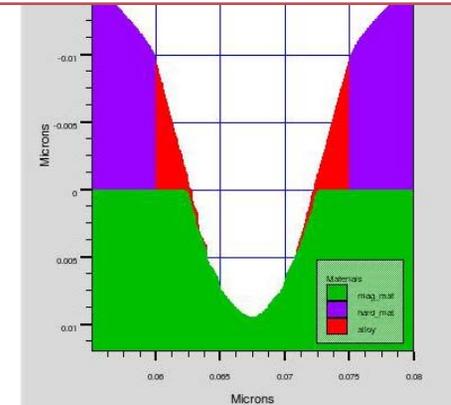
36nm wide opening, 18nm deep



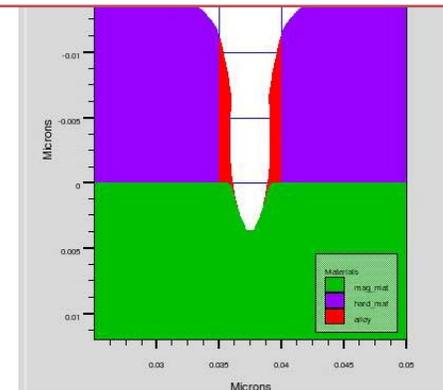
23nm wide opening, 15nm deep

Media etch performance can be improved with sturdier and thinner hard masks

15nm wide opening, 9nm deep



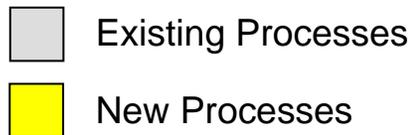
5nm wide opening, 4nm deep



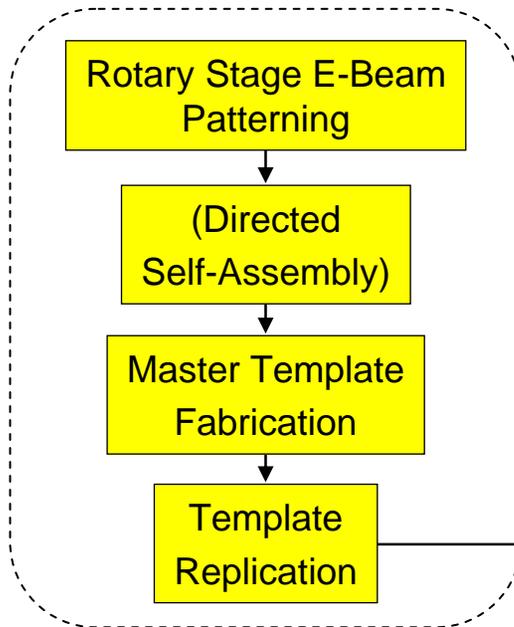
- **HGST investigated potential high volume patterned media etch equipment from Veeco, Cannon-Anelva, and Intevac**
- **Lifecycle problems and grid replacement costs were problems for ion beam etch systems**
- **In 2010 HGST purchased an Intevac disk etch tool that utilizes CCP and ICP stations for reactive ion and sputter etch processes, as well as disk planarization**
- **High disk throughput, ~500 dph can be achieved with a proper process flow**



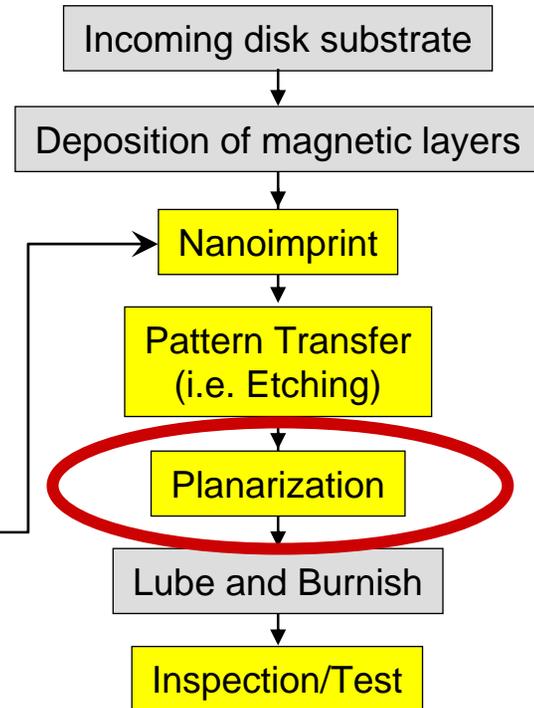
Lean 200 Disk Platform



Template Fabrication

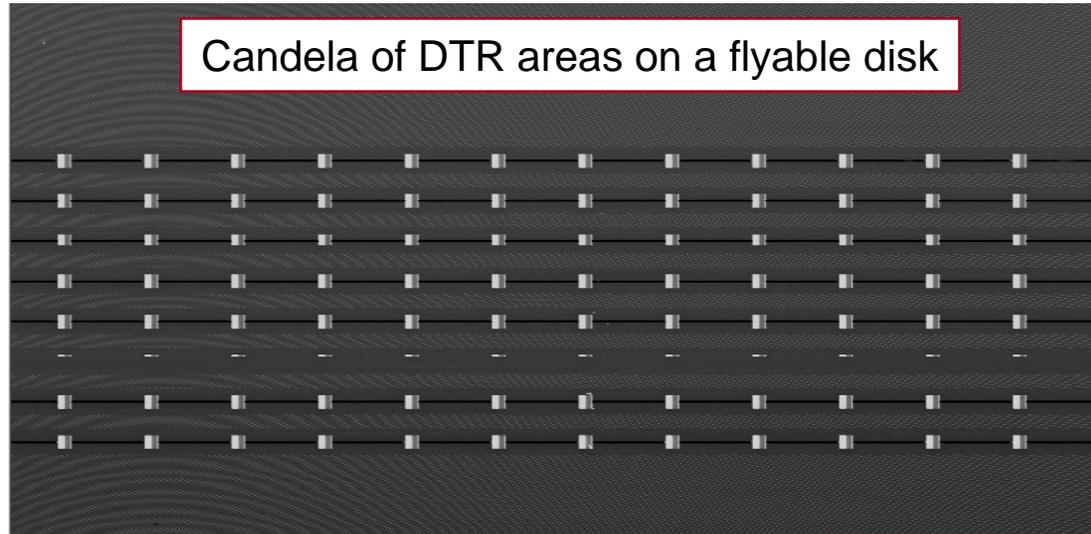


Media Fabrication Process

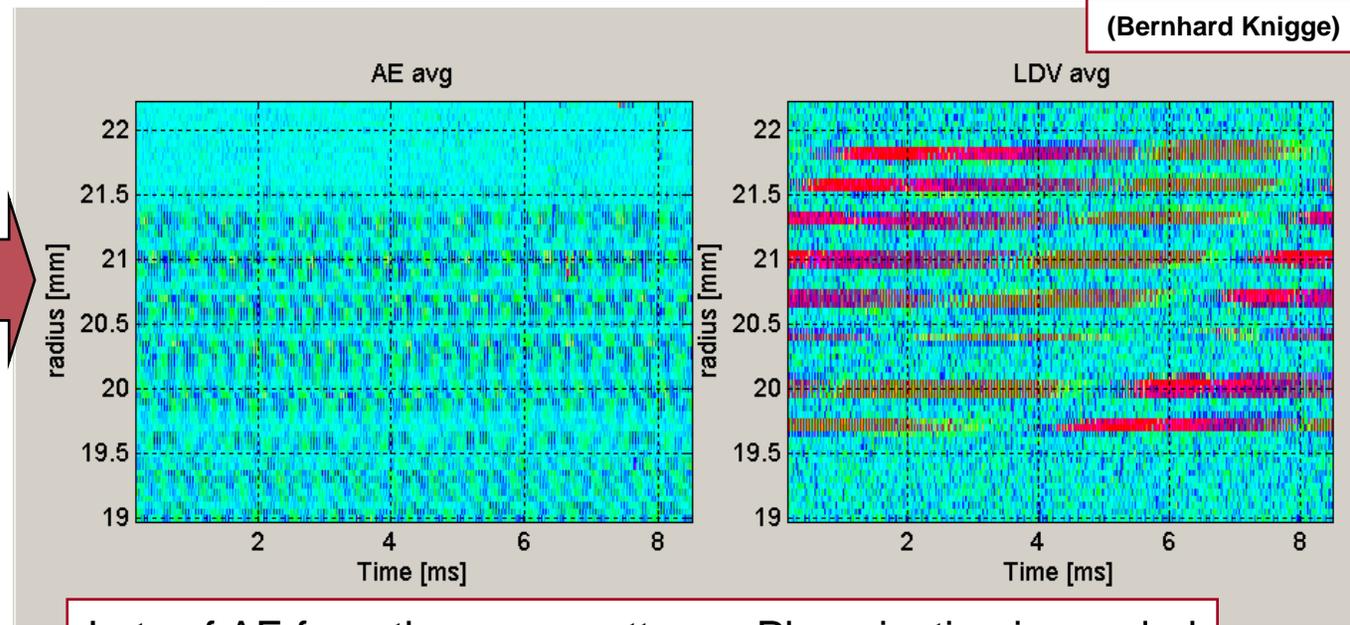


- The imprint pattern transfer process can produce clean and flyable disks
- Finished disks can be tested on the drag tester, spin stand, and in prototype drives
- Variations in pattern density result in fly height modulation

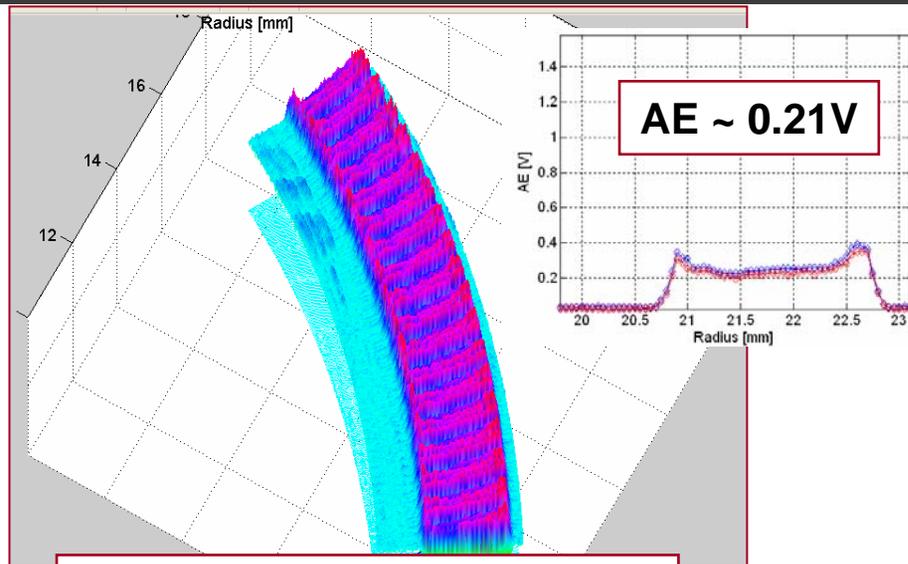
Candela of DTR areas on a flyable disk



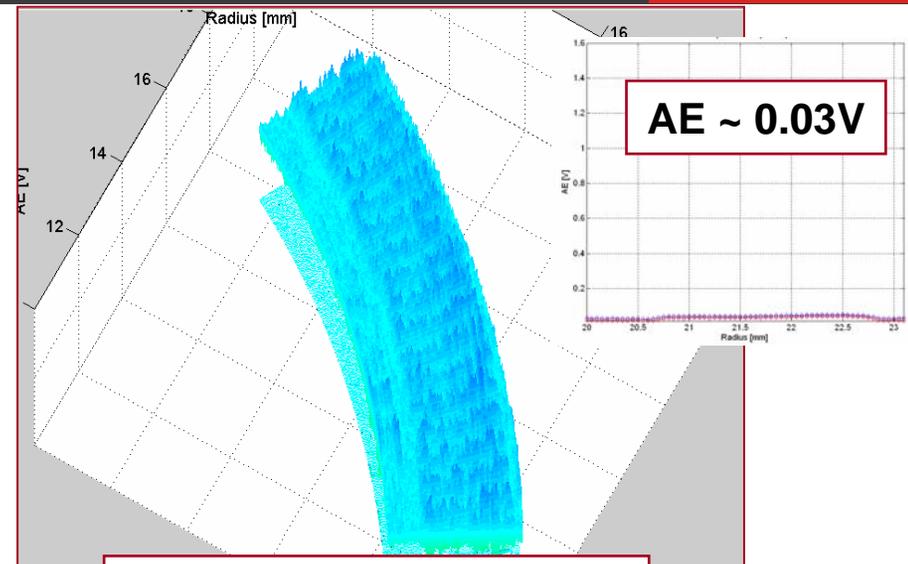
- AE and LDV maps on an imprinted disk
- Fly height ~3.0nm



Lots of AE from the servo patterns: Planarization is needed

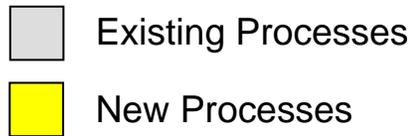


DTM Media Un-planarized

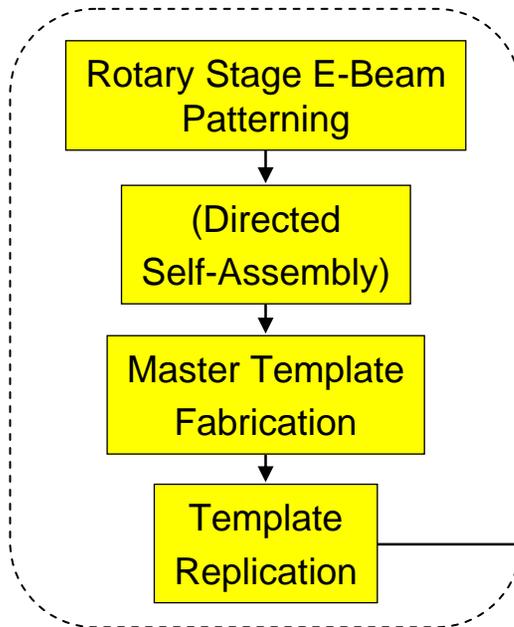


DTM Media Planarized

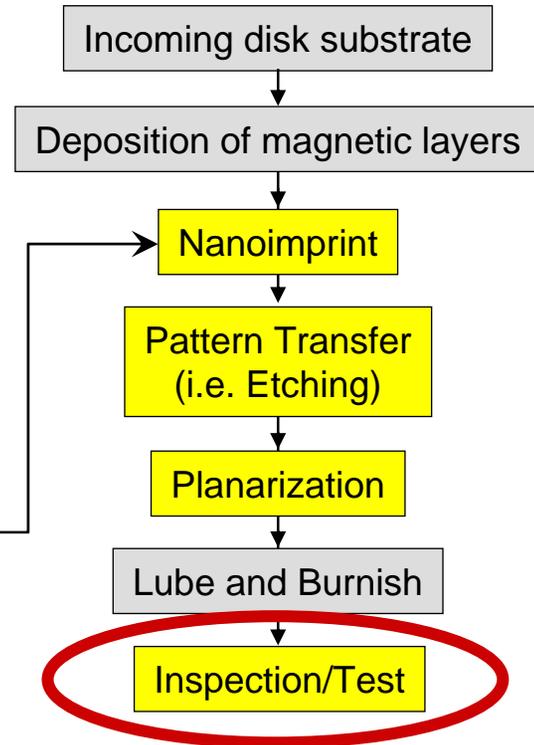
- Imprint planarization has been used to fill 20nm deep DTM grooves
- Acoustic emission data is shown from a read/write head flying at 3nm height on a 2mm wide DTM area
 - Large acoustic emission is due to unplanarized servo patterns (left image)
 - DTM patterns with a 5nm recess have a much lower acoustic emission (right image)
- The process is clean enough that read-write heads can fly and perform testing



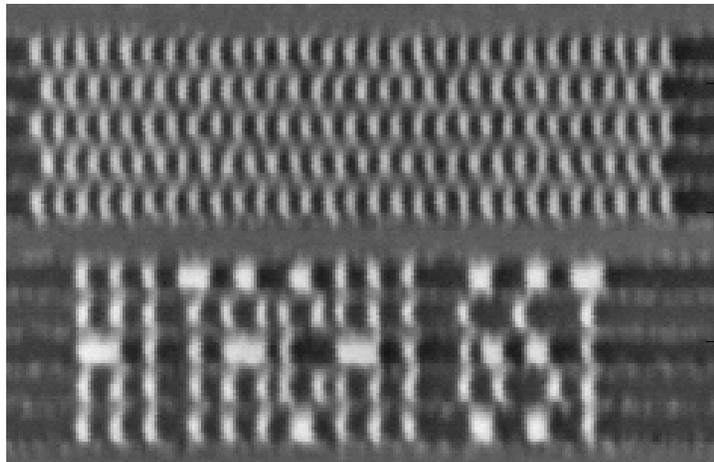
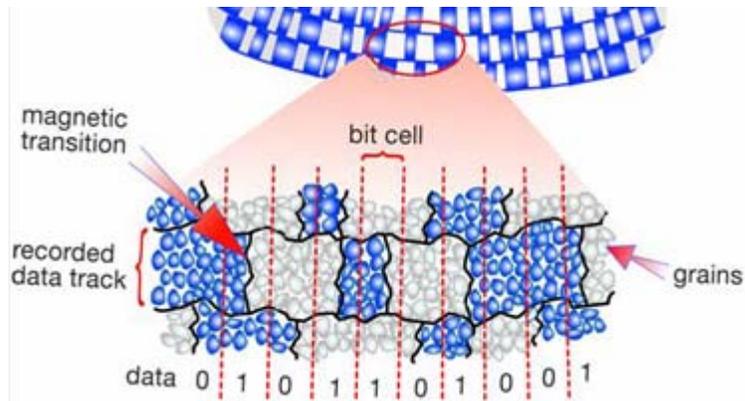
Template Fabrication



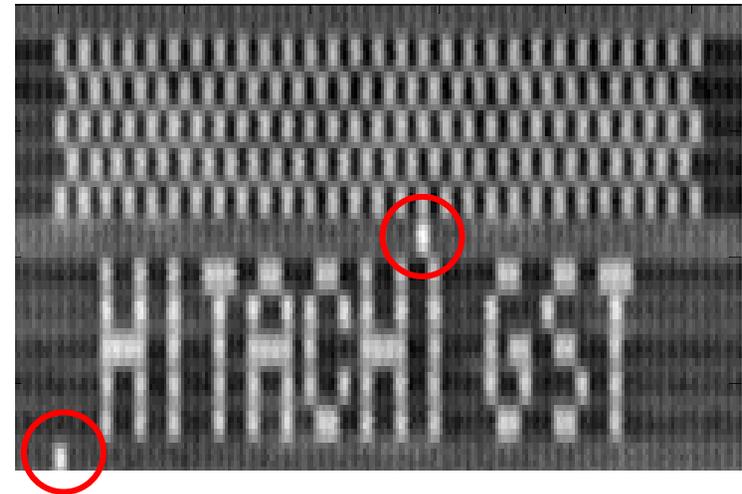
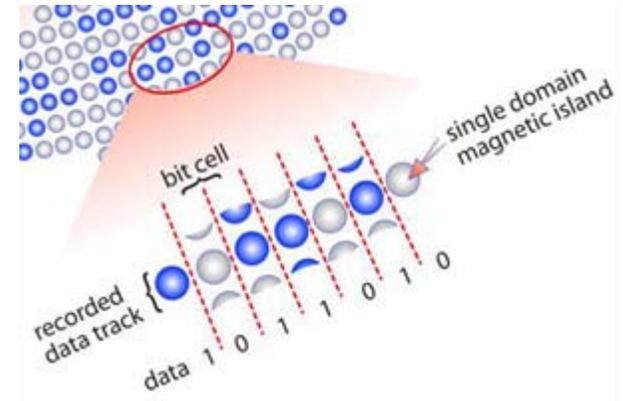
Media Fabrication Process



Conventional granular media



Bit patterned media



- Bit shape: defined by head field profile (curved) vs. patterned island shape
- Noise: grain statistics vs. patterning roughness, write errors, and tolerances
- Thermal stability and bit errors: grain reversal vs. island reversal

Drag tester results: M. Grobis

100 Gb/in²



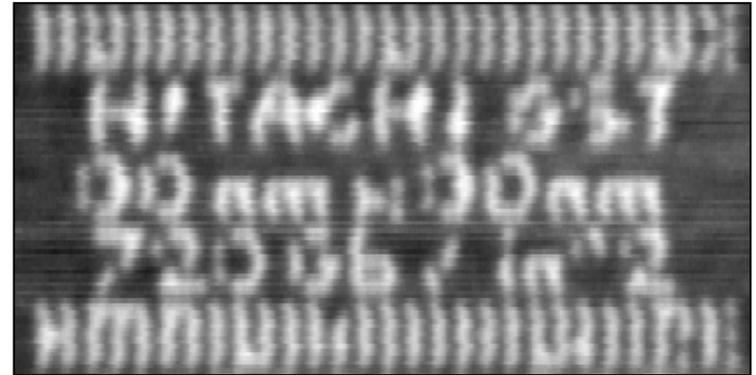
200 Gb/in²



300 Gb/in²



720 Gb/in²



500
Gb/in²

720
Gb/in²

2007

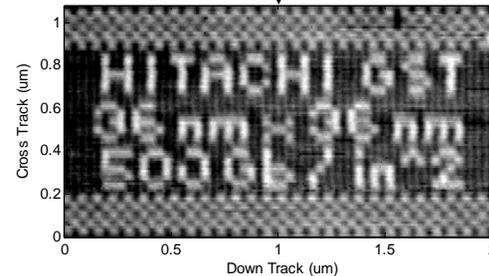
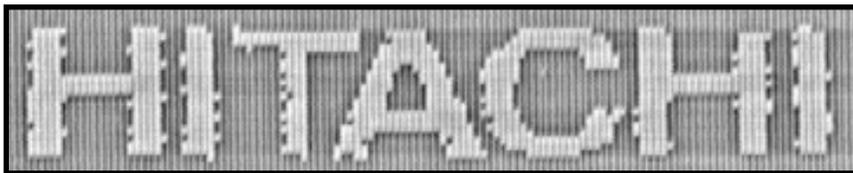
2008

2009

2010

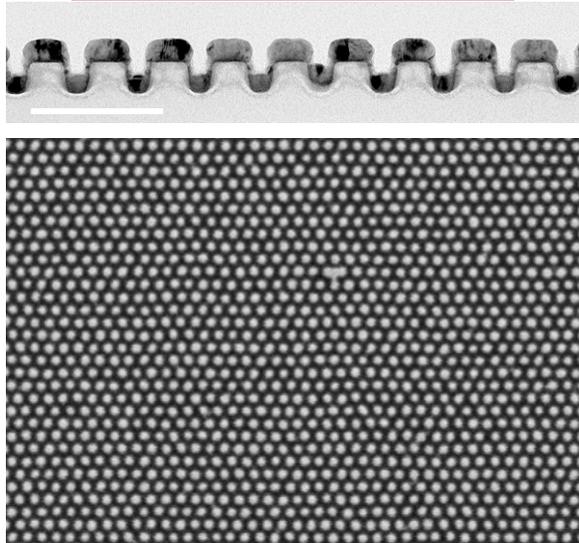
2011

~ 10 Gb/in² (multiple islands/bit)



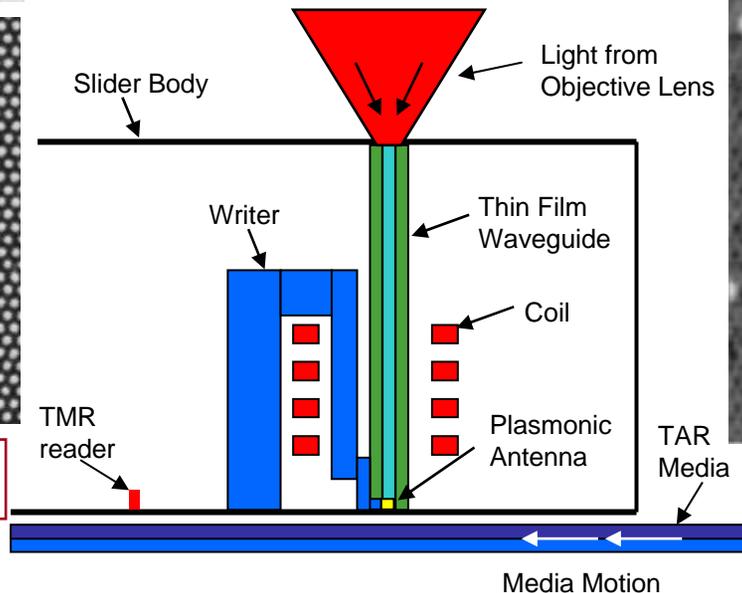
500 Gb/in²

Co/Pd Media on Pre-Patterned Substrate

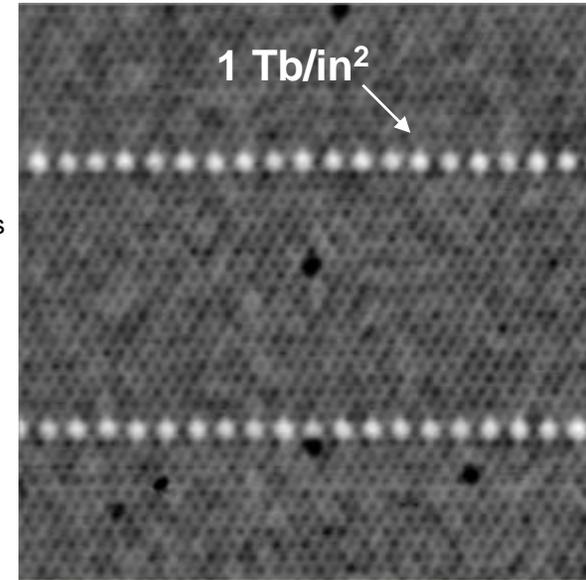


1Tb/in² = 27nm pitch

Schematic of a TAR Head



MFM Image of Tracks



- Combination of TAR and BPM (BP-TAR) is capable of extremely small track pitch
 - 24nm track pitch with similar notch width in near field optical aperture
 - Near-field focusing on islands
 - Restricted lateral heat flow

B. Stipe et al., Nature Photonics 2010

- Five times lower threshold laser power compared to continuous media using same head

- Patterned Media is a potential solution for extending the areal density growth of magnetic data recording beyond the limits of conventional media
- The small size and tolerances required, down to $1 \sigma = \sim 1 \text{ nm}$, suggest that master pattern generation will be done with a rotary stage e-beam tool plus lithographically assisted self assembly
- Nano-imprint template fabrication relies on high quality dry etch recipes
- Pattern transfer of nano-imprinted disks can create flyable disks
- To be competitive patterned media must achieve both high areal density and low cost manufacturing
- Patterned media combined with thermal assisted recording shows promising benefits to maintain the needed growth in bit areal density